

Product Overview

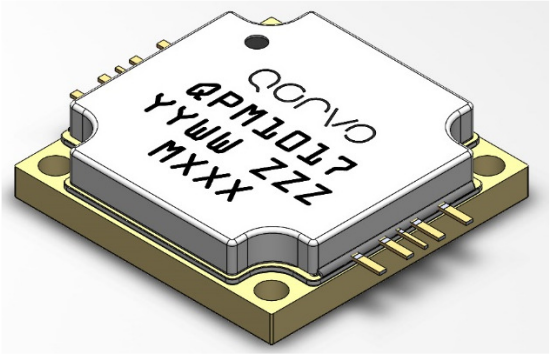
Qorvo’s QPM1017 is a packaged, high-power C-band amplifier module, fabricated on Qorvo’s production 0.15 μm GaN on SiC process (QGaN15). Covering 5.7 – 7 GHz, the QPM1017 provides 100 W of saturated output power with 18 dB of large signal gain while achieving > 35% power-added efficiency. For satellite communications applications, QPM1017 provides 40 W linear power with 25 dBc third order intermodulation distortion products.

The QPM1017 is packaged in a 10-lead 19.05 x 19.05 mm bolt-down package with a Cu base for superior thermal management. It can support a variety of operating conditions to best support system requirements.

To simplify system integration, QPM1017 is fully matched to 50 ohms. Input port is DC grounded for improved ESD performance, output port is AC coupled with integrated DC blocking capacitor.

The QPM1017 is ideal for supporting communications and radar applications in both commercial and military markets

RoHS compliant

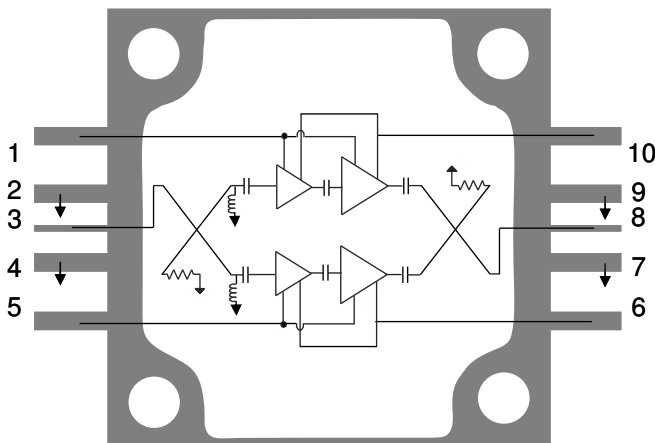


Key Features

- Frequency Range: 5.7 – 7 GHz
- P_{SAT} ($P_{IN} = 32$ dBm): 50 dBm
- PAE ($P_{IN} = 32$ dBm): > 35 %
- Power Gain ($P_{IN} = 32$ dBm): 18 dB
- IM3 ($P_{OUT}/\text{Tone} = 43$ dBm): -25 dBc
- Small Signal Gain: > 24 dB
- Bias: $V_D = +24$ V, $I_{DQ} = 3.4$ A, $V_G = -2.5$ V typ.
- Dimensions: 19.05 x 19.05 x 4.5 mm

Performance is typical across frequency. Please reference electrical specification table and data plots for more details.

Functional Block Diagram



Applications

- C-Band Radar
- Satellite Communications

Ordering Information

| Part No. | Description |
|------------|---|
| QPM1017 | 5.7 – 7 GHz 100 W GaN Power Amplifier Module (10 pcs. pack) |
| QPM1017S2 | Samples (2 pcs. pack) |
| QPM1017EVB | Evaluation Board for QPM1017 |

Absolute Maximum Ratings

| Parameter | Value / Range |
|---|----------------------------------|
| Drain Voltage (V_D) | 29.5 V |
| Gate Voltage Range (V_G) | -6 V to 0 V |
| Drain Current (I_D) | 20 A |
| Gate Current (I_G) | See plot page 18 |
| Power Dissipation (P_{DISS}), 85 °C | Pulsed, 360 W CW, 200 W |
| Input Power (P_{IN}), Pulsed, 50 Ω , $V_D = 24$ V, $I_{DQ} = 3.4$ A, $T_{BASE} = 85$ °C, | 36 dBm |
| Input Power (P_{IN}), Pulsed, 3:1 VSWR, $V_D = 24$ V, $I_{DQ} = 3.4$ A, $T_{BASE} = 85$ °C | 36 dBm |
| Mounting Temperature | Refer to Assembly Notes, page 22 |
| Storage Temperature | -55 to +150 °C |

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

Recommended Operating Conditions

| Parameter | Min | Typ. | Max | Units |
|---------------------------------------|---------------------|------|-----|-------|
| Drain Voltage (V_D) | | +24 | +24 | V |
| Drain Current, Quiescent (I_{DQ}) | | 3.4 | | A |
| Drain Current, RF (I_{D_Drive}) | See chart page 4, 7 | | | A |
| Gate Voltage Typ. Range (V_G) | -2 to -2.9 | | | V |
| Gate Current, RF (I_{G_Drive}) | See chart page 4, 7 | | | mA |
| Operating Temp. Range (T_{BASE}) | -40 | | +85 | °C |

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

Electrical Specifications

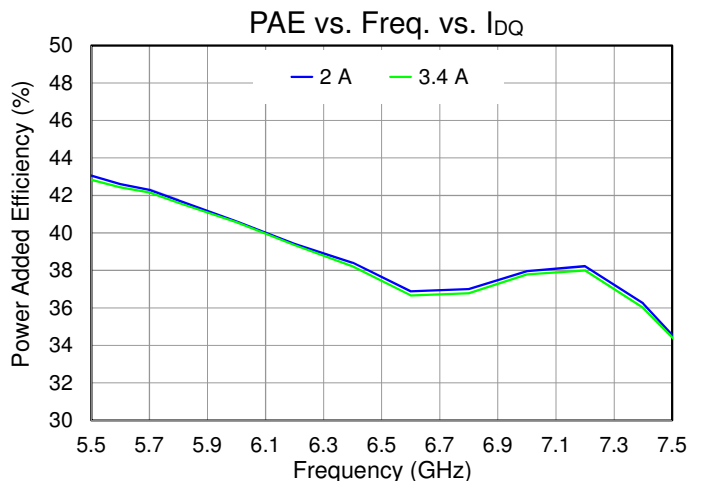
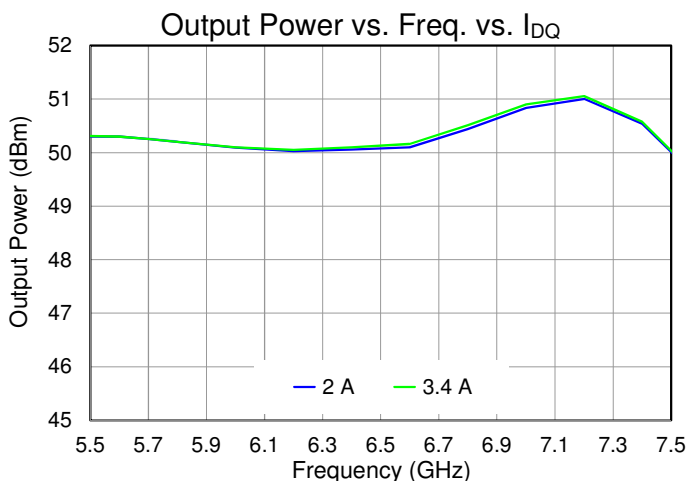
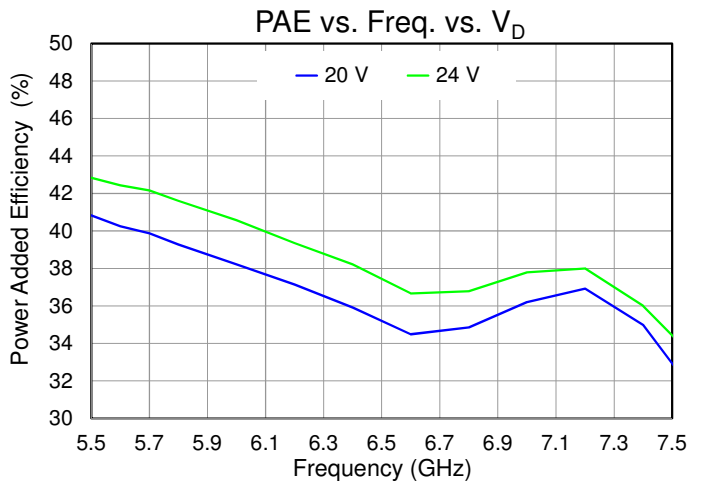
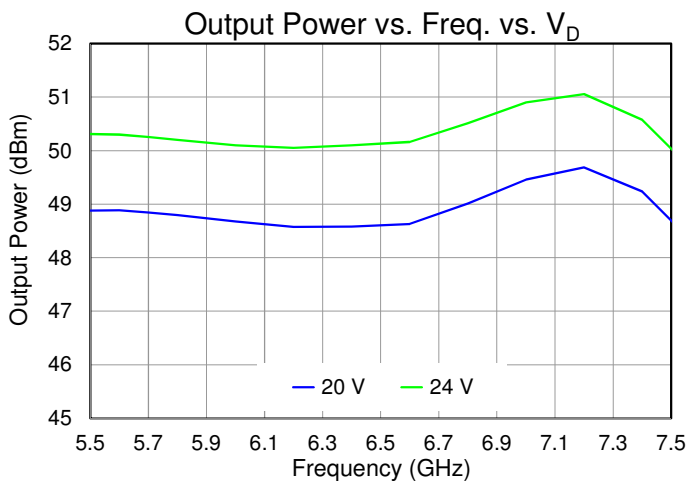
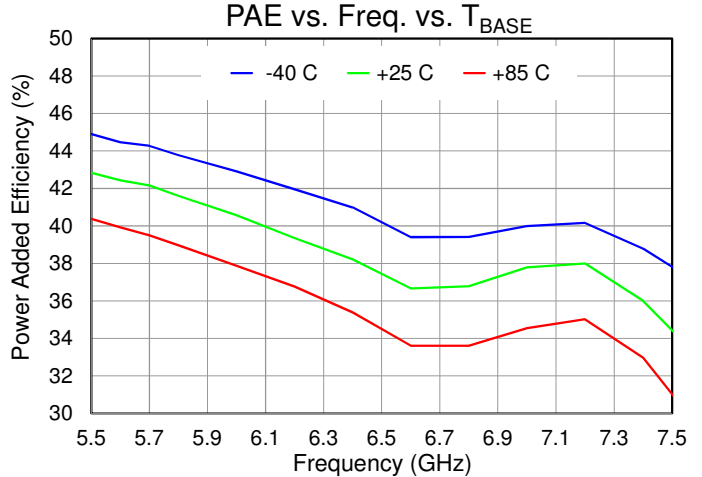
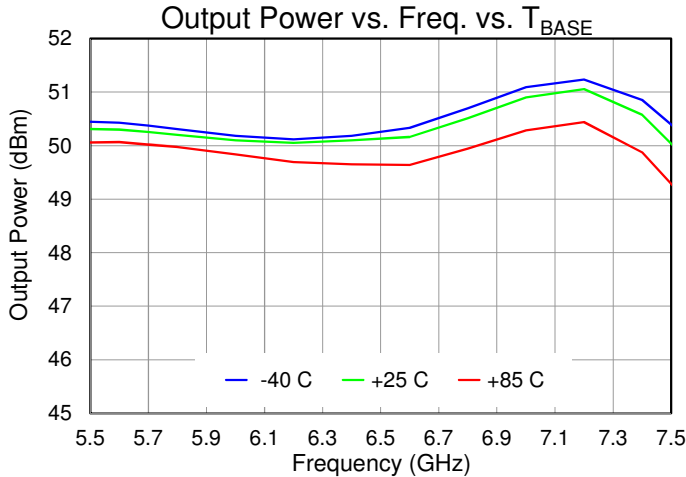
| Parameter | Conditions ⁽¹⁾ ⁽²⁾ | Min | Typ. | Max | Units |
|---|---|-------|--------|------|--------|
| Operational Frequency Range | | 5.7 | | 7 | GHz |
| Output Power at Saturation, P_{SAT} | $P_{IN} = +32$ dBm, Pulsed | | 50 | | dBm |
| Power Added Efficiency, PAE | $P_{IN} = +32$ dBm, Pulsed | | 35 | | % |
| Large Signal Gain | $P_{IN} = +32$ dBm, Pulsed | | 18 | | dB |
| Small Signal Gain, S_{21} | CW | | 24 | | dB |
| Input Return Loss, IRL | CW | | 18 | | dB |
| Output Return Loss, ORL | CW | | 20 | | dB |
| 3 RD Intermodulation Products, IM3 | $P_{OUT}/Tone = 43$ dBm; Freq. = 5.7, 6.4, 7 GHz; $\Delta f = 5$ MHz, CW | | -25 | | dBc |
| 5 TH Intermodulation Products, IM5 | $P_{OUT}/Tone = 43$ dBm; Freq. = 35 GHz; $\Delta f = 5$ MHz, CW | | -35 | | dBc |
| P_{SAT} Temperature Coefficient | $T_{DIFF} = -40$ °C to +85 °C; $P_{IN} = +26$ dBm, Pulsed | | -0.007 | | dBm/°C |
| S_{21} Temperature Coefficient | $T_{DIFF} = -40$ °C to +85 °C, CW | | -0.065 | | dB/°C |
| Gate Leakage, I_G | $V_D = +10$ V, $V_G = -4$ V, no RF | -70.4 | | 0.01 | mA |

Notes:

- Test conditions unless otherwise noted: Pulsed $V_D = +24$ V, $I_{DQ} = 3.4$ A, $V_G = -2.5$ V +/- typical, DC = 20%, PW = 150 us, $T_{BASE} = +25$ °C, $Z_0 = 50$ Ω
- T_{BASE} is back side of QPM1017

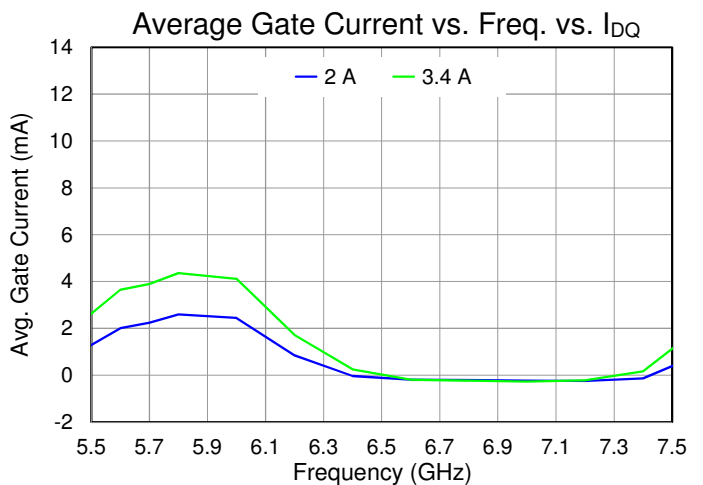
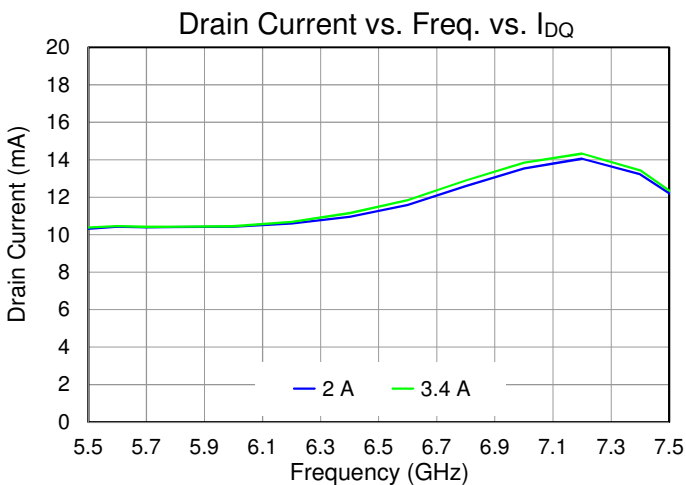
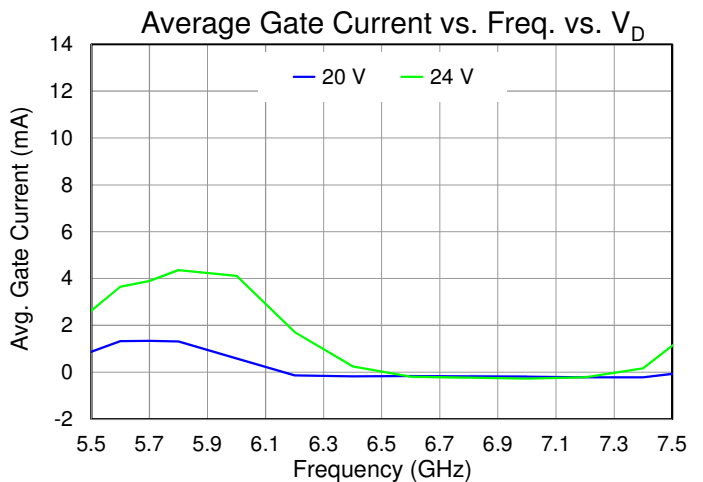
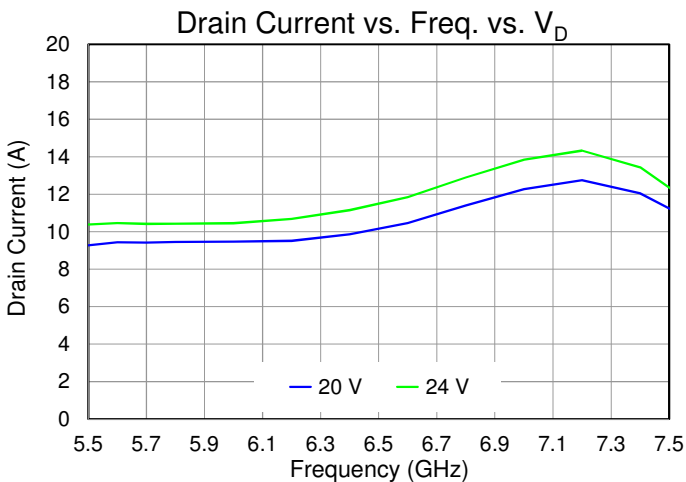
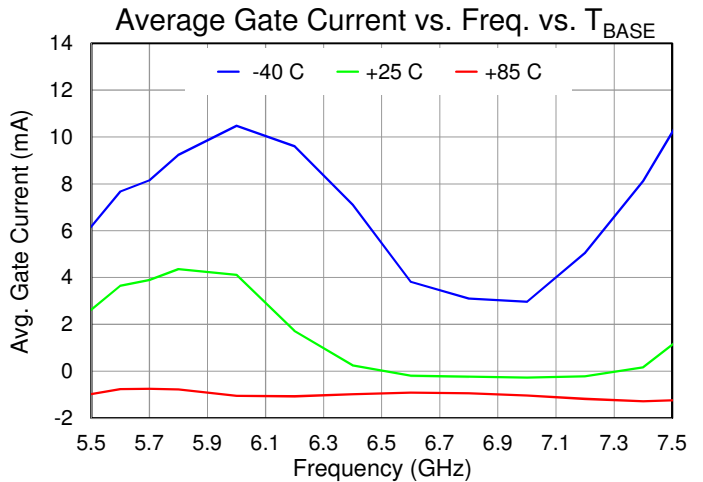
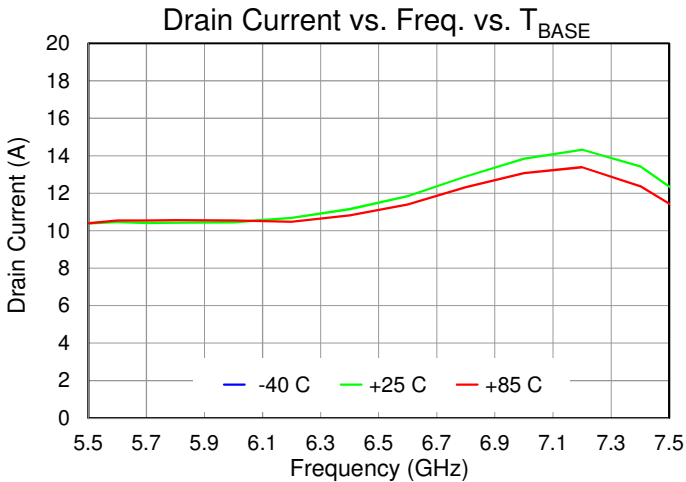
Performance Plots – Large Signal

Test conditions, unless otherwise noted: Pulsed $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$, Duty Cycle = 20%, $PW = 150\text{ }\mu\text{s}$, $P_{IN} = 32\text{ dBm}$, $T_{BASE} = +25\text{ }^\circ\text{C}$



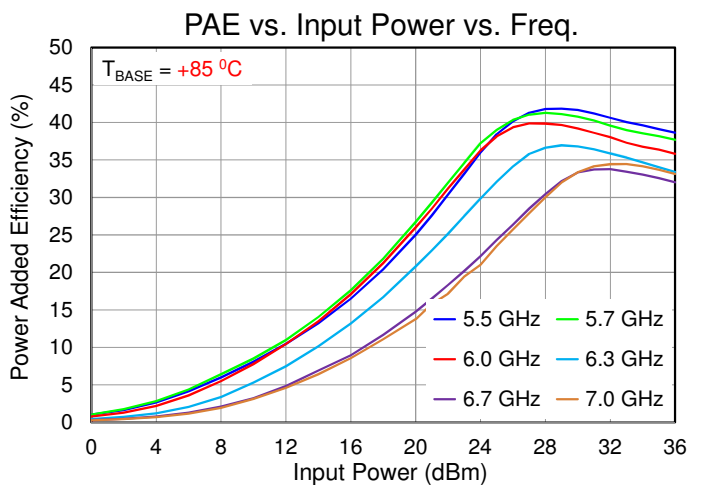
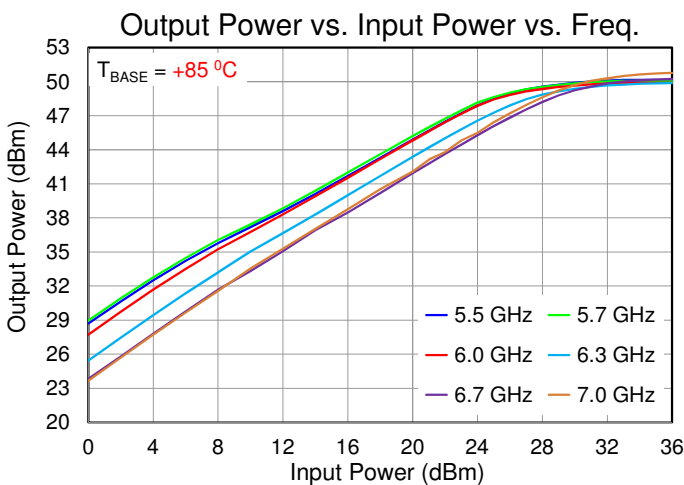
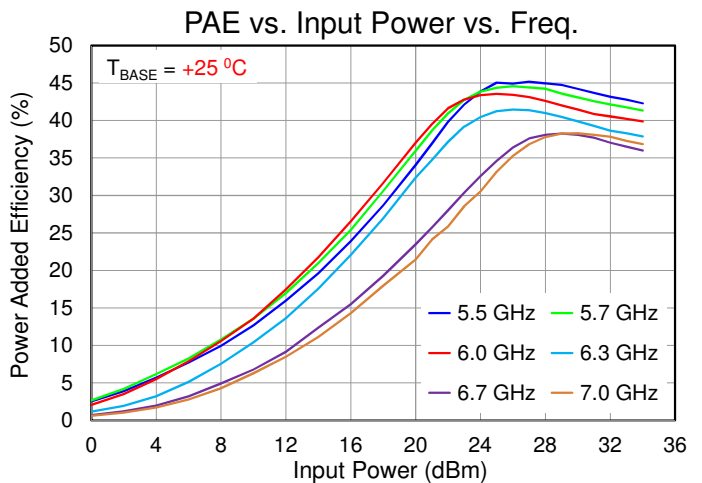
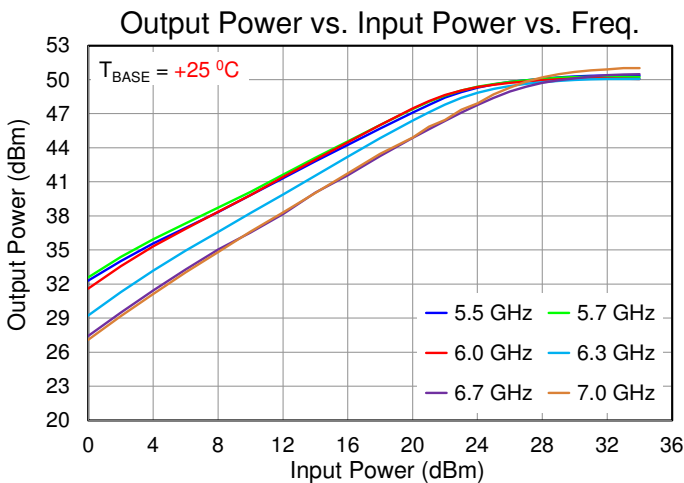
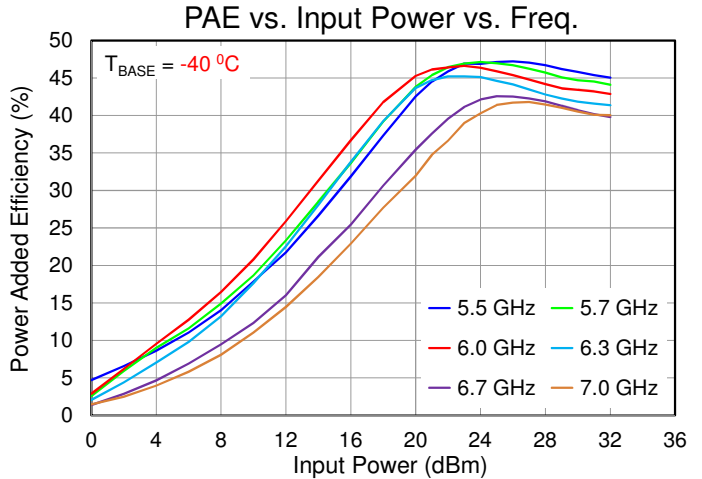
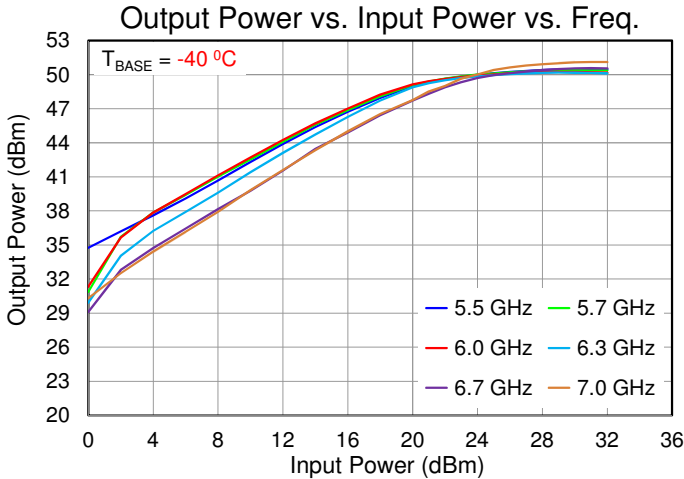
Performance Plots – Large Signal

Test conditions, unless otherwise noted: Pulsed $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$, Duty Cycle = 20%, $PW = 150\text{ }\mu\text{s}$, $P_{IN} = 32\text{ dBm}$, $T_{BASE} = +25\text{ }^\circ\text{C}$

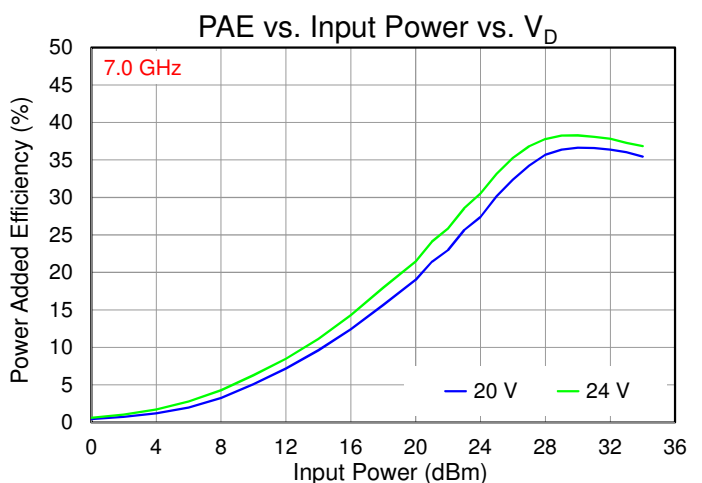
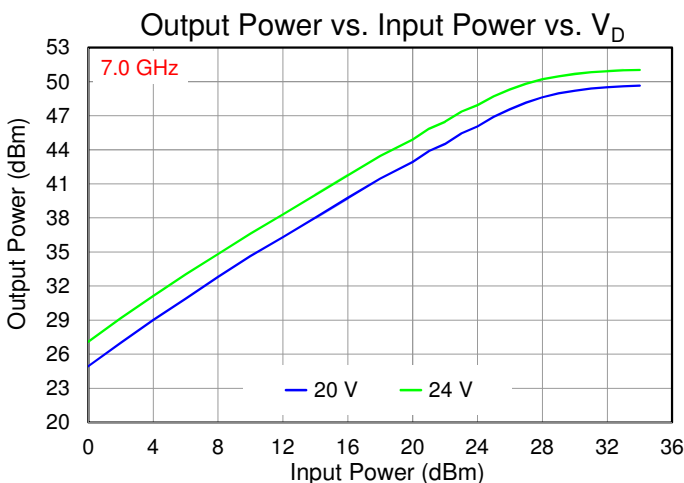
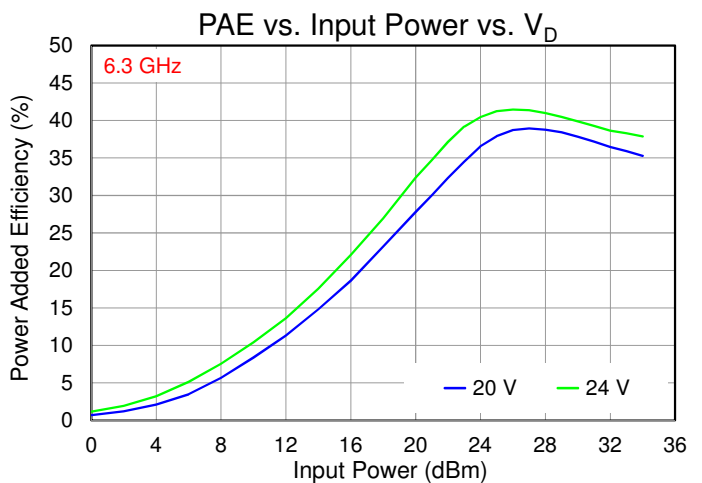
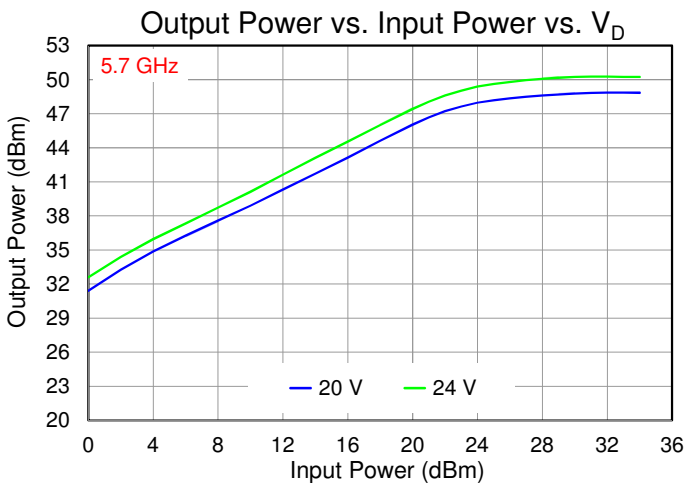
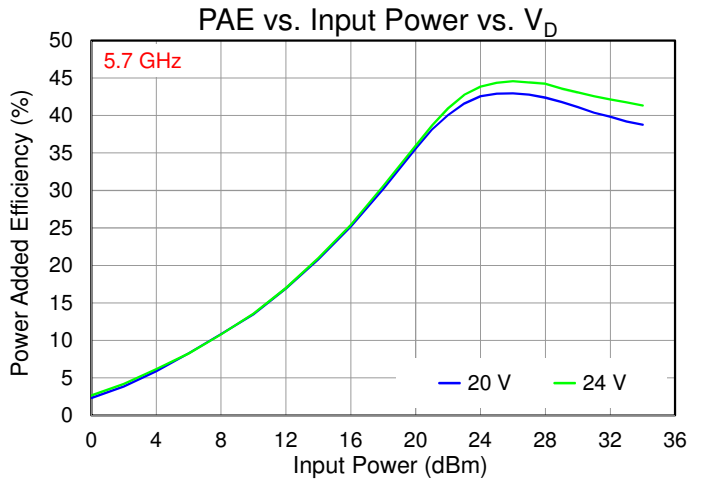
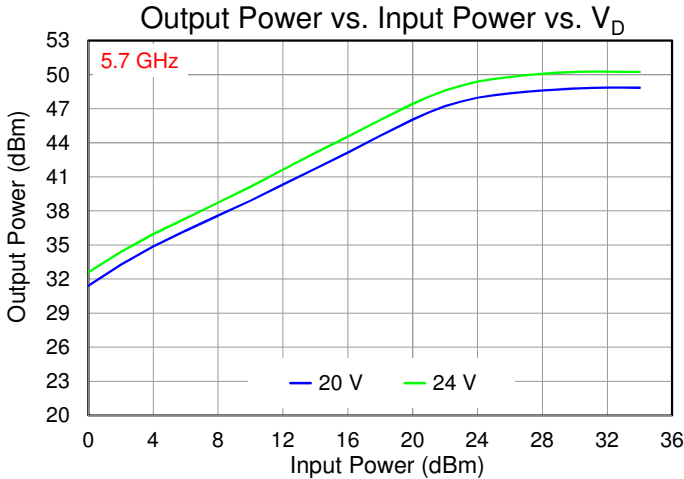


Performance Plots – Large Signal

Test conditions, unless otherwise noted: Pulsed $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$, Duty Cycle = 20%, $PW = 150\text{ }\mu\text{s}$, $P_{IN} = 32\text{ dBm}$, $T_{BASE} = +25\text{ }^\circ\text{C}$

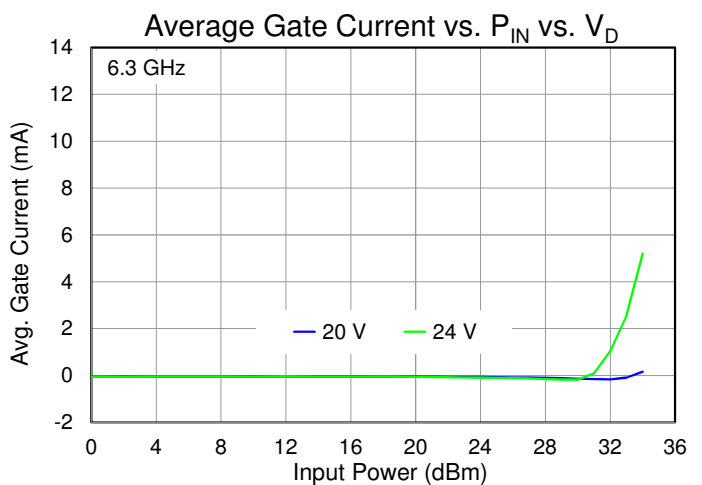
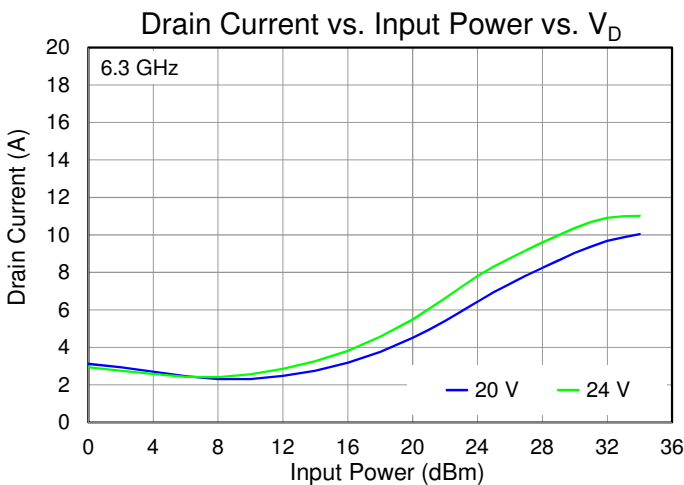
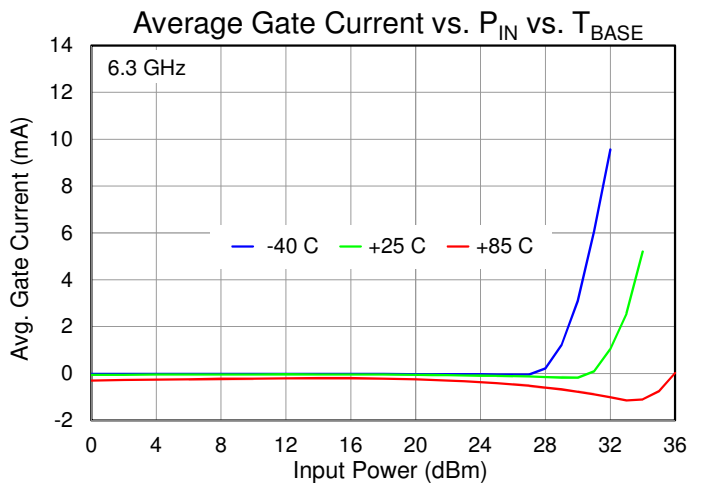
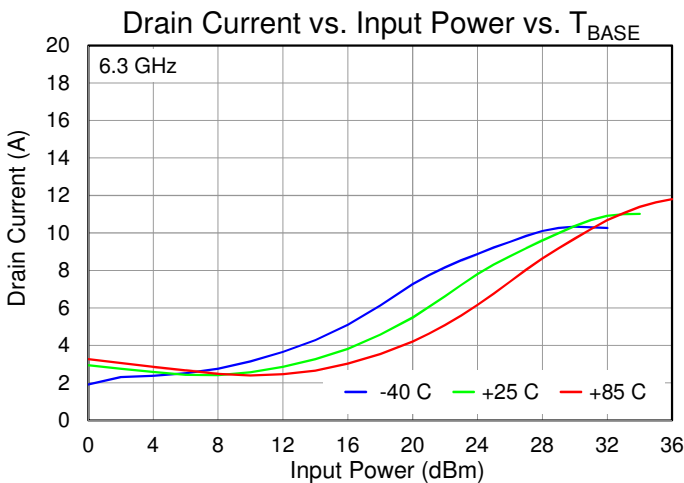
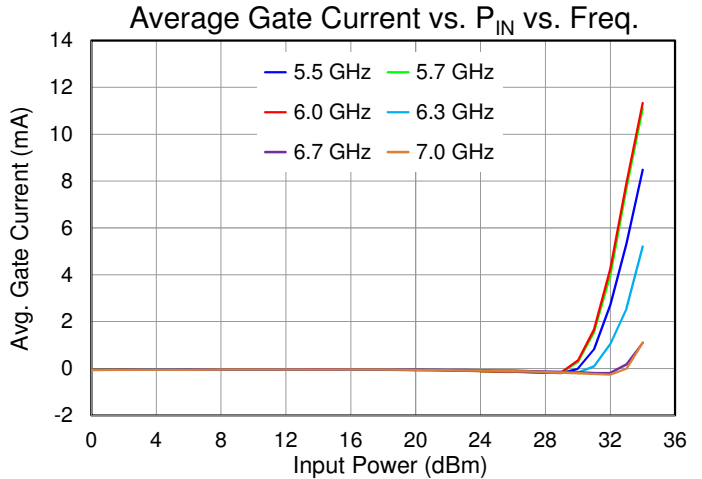
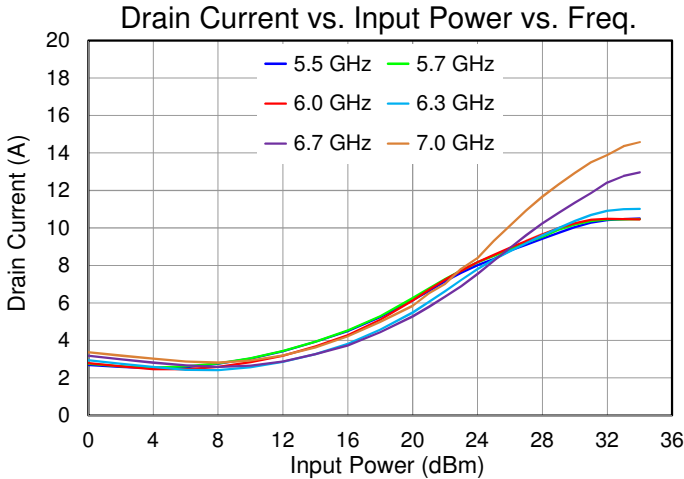


Performance Plots – Large Signal

 Test conditions, unless otherwise noted: **Pulsed** $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$, Duty Cycle = 20%, $PW = 150\text{ }\mu\text{s}$, $P_{IN} = 32\text{ dBm}$, $T_{BASE} = +25\text{ }^\circ\text{C}$


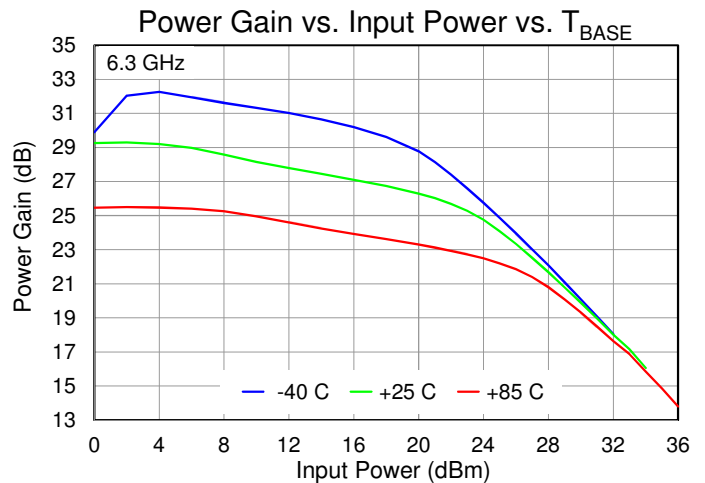
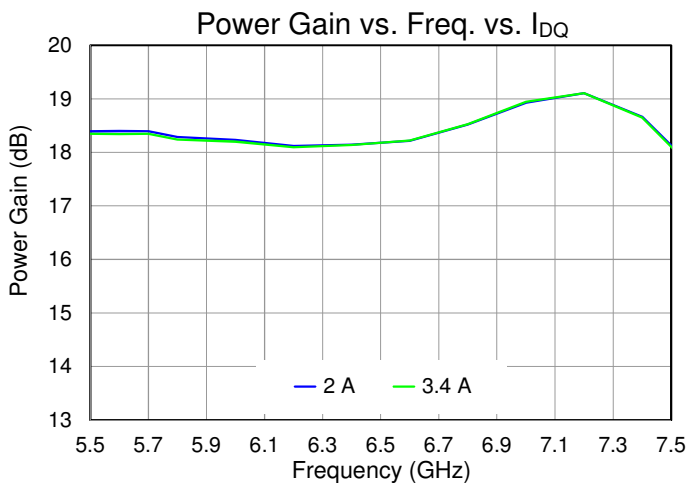
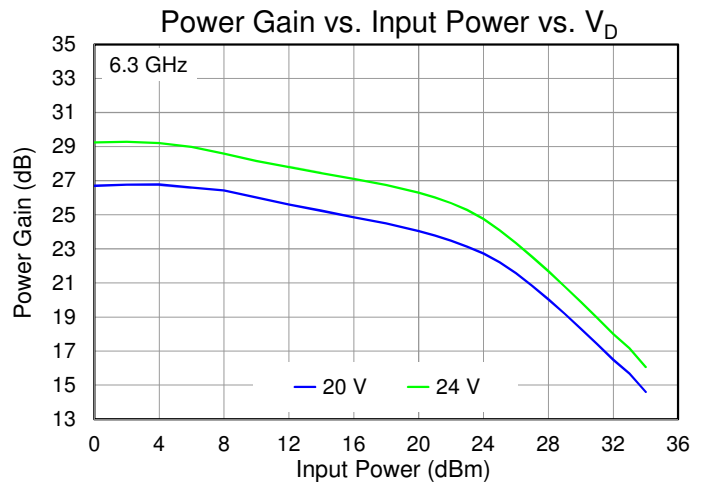
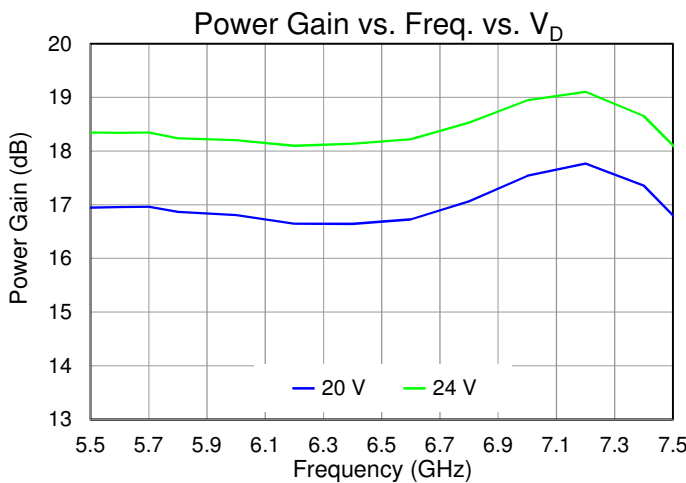
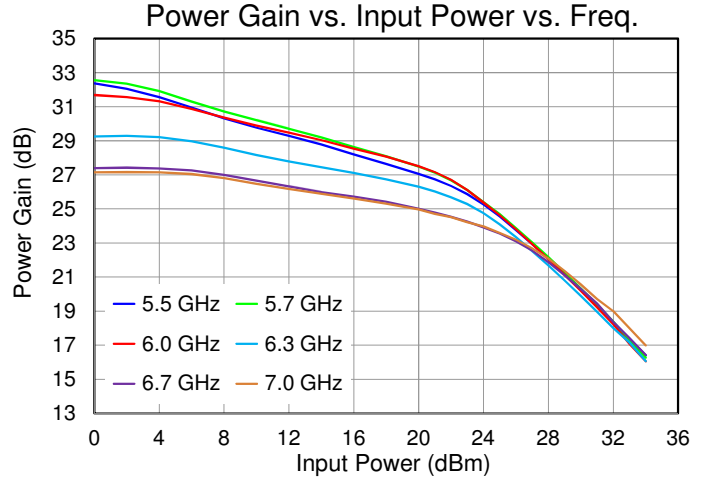
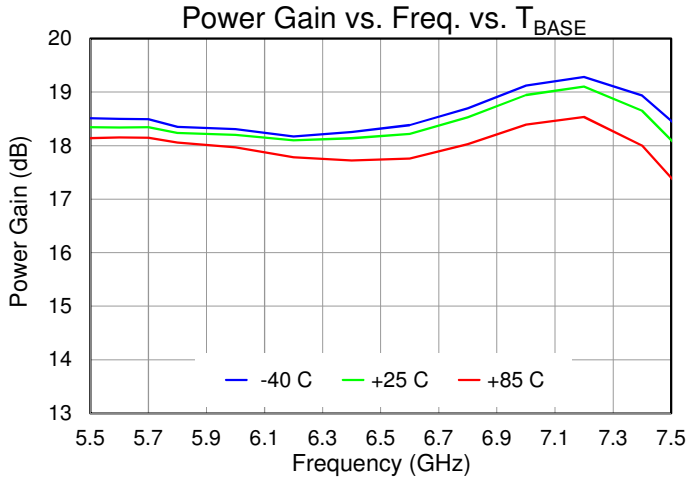
Performance Plots – Large Signal

Test conditions, unless otherwise noted: **Pulsed** $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$, Duty Cycle = 20%, $PW = 150\text{ }\mu\text{s}$, $P_{IN} = 32\text{ dBm}$, $T_{BASE} = +25\text{ }^\circ\text{C}$



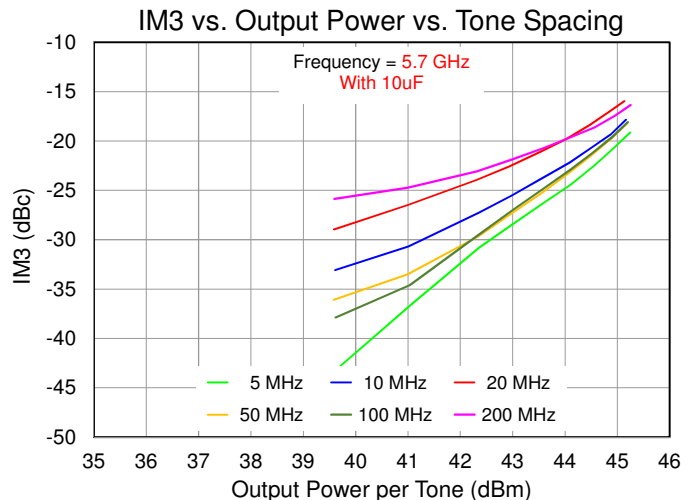
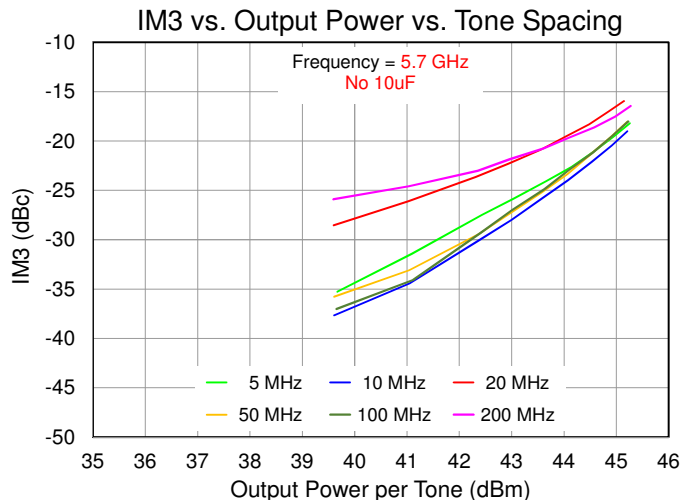
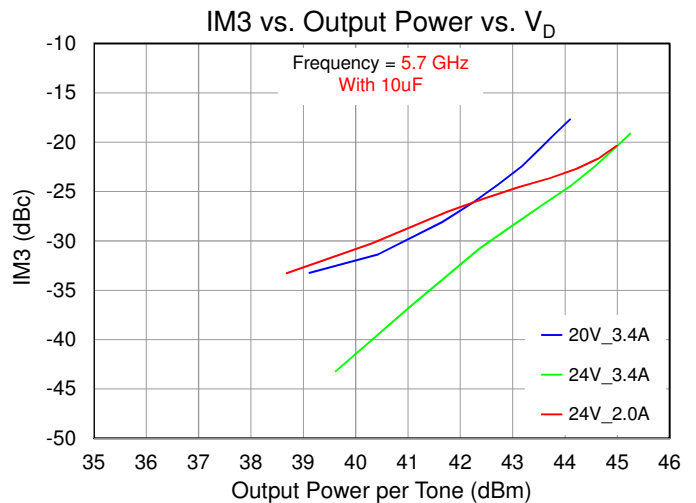
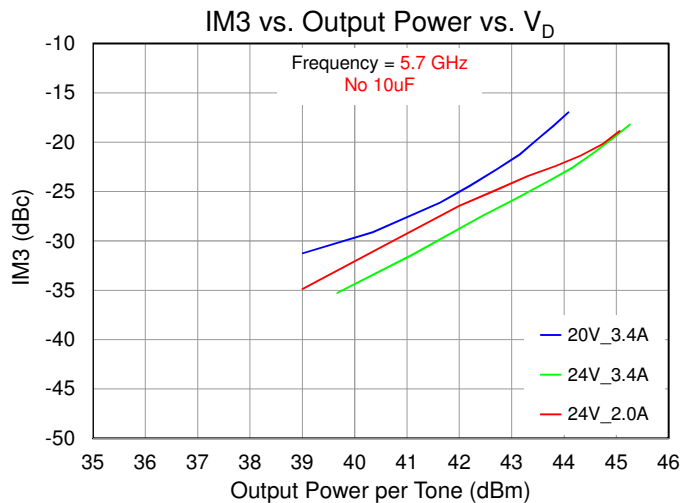
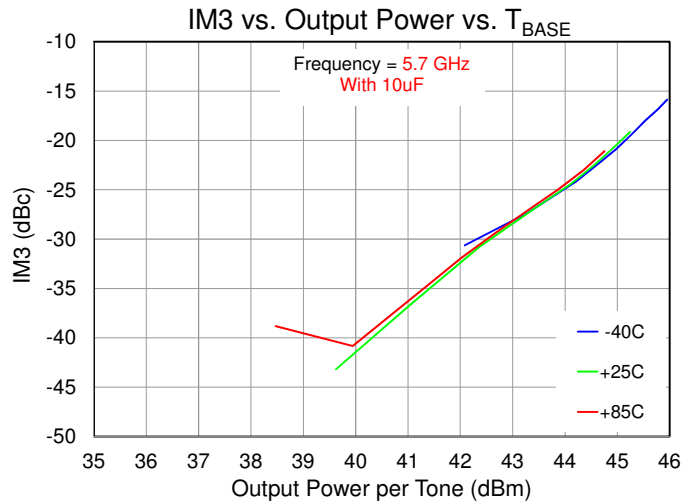
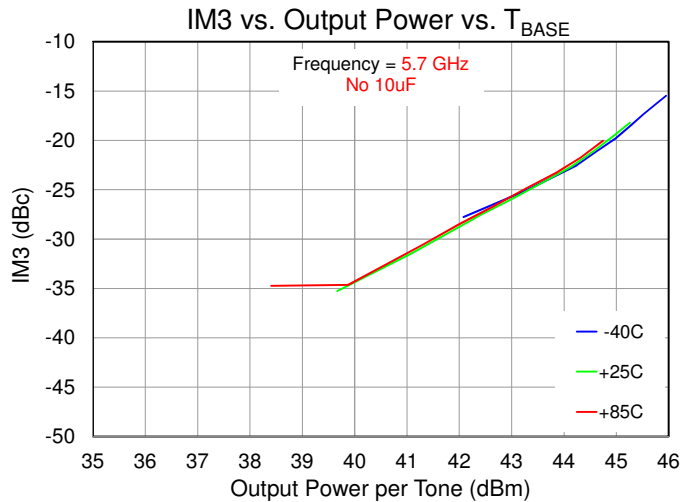
Performance Plots – Large Signal

Test conditions, unless otherwise noted: **Pulsed** $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$, Duty Cycle = 20%, $PW = 150\text{ }\mu\text{s}$, $P_{IN} = 32\text{ dBm}$, $T_{BASE} = +25\text{ }^\circ\text{C}$



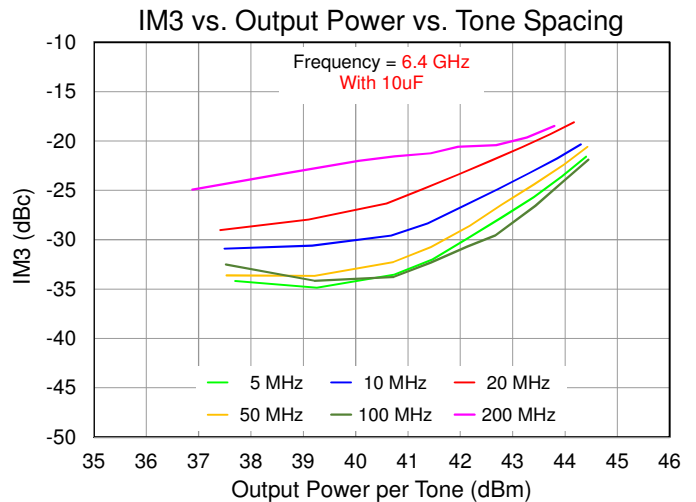
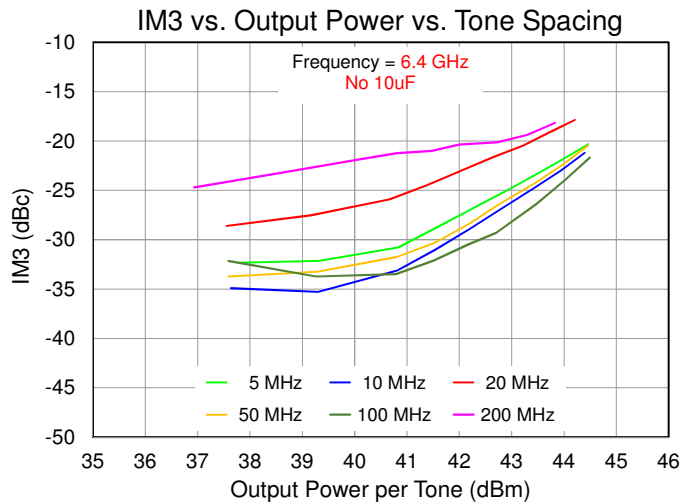
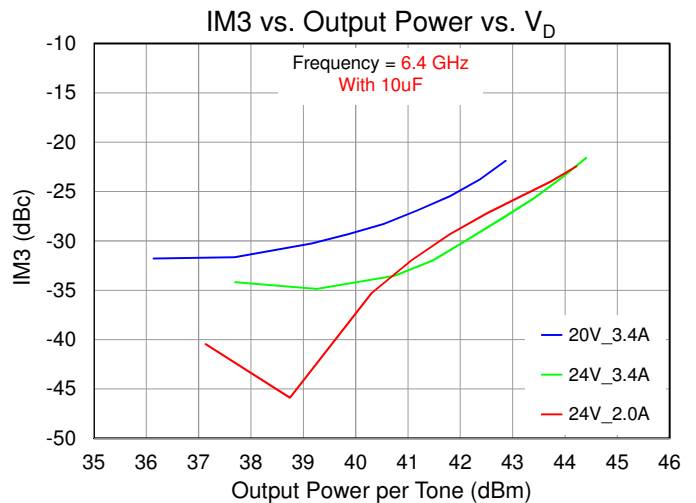
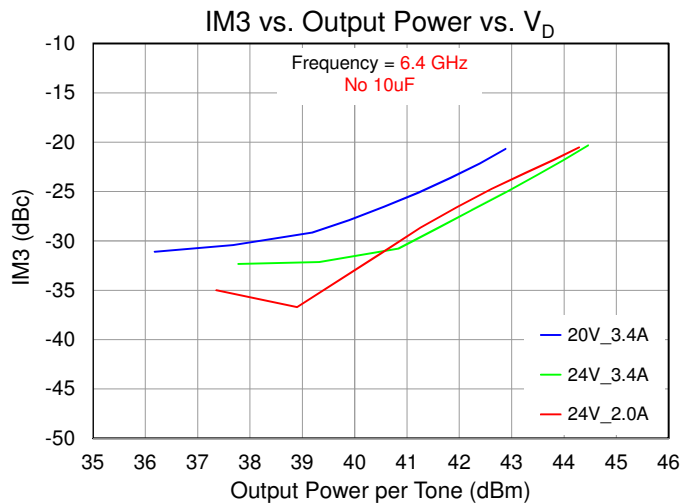
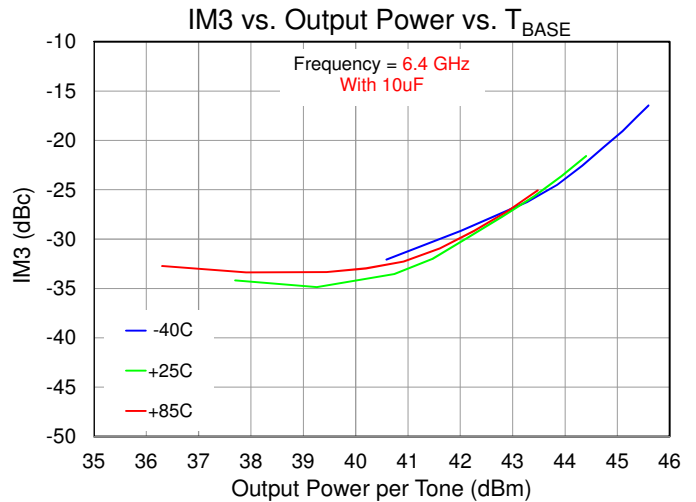
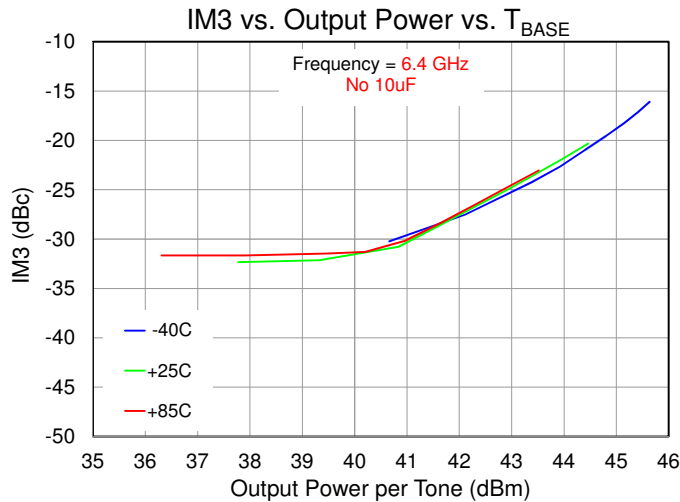
Performance Plots – Large Signal

Test conditions, unless otherwise noted: CW $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$, Tone Spacing = 5 MHz, $T_{BASE} = +25\text{ }^\circ\text{C}$, with/without 10uF at drain (C9, C12)



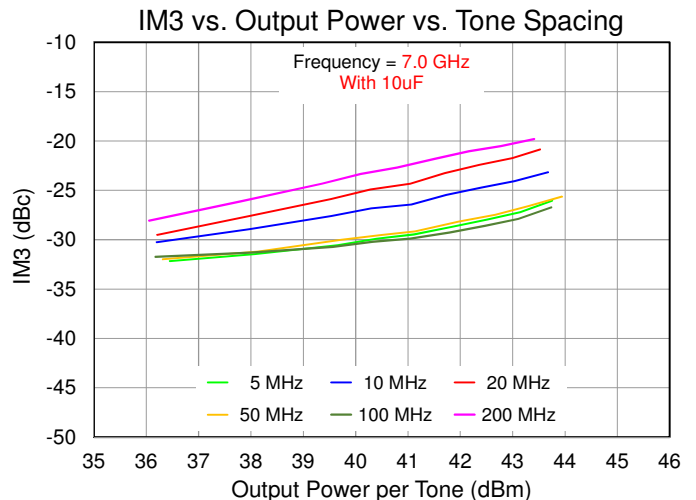
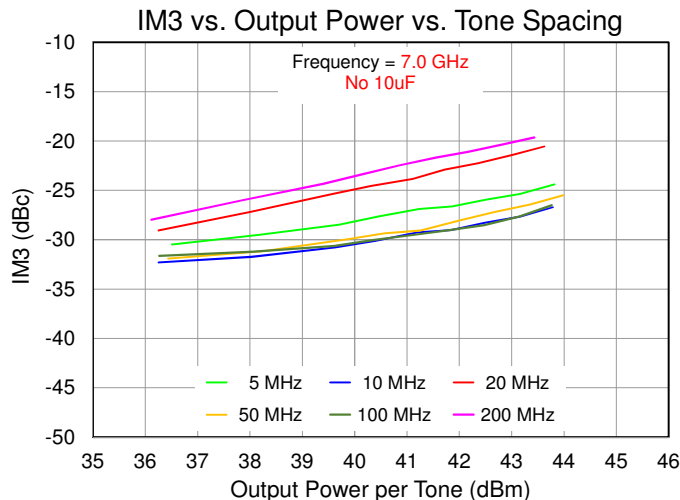
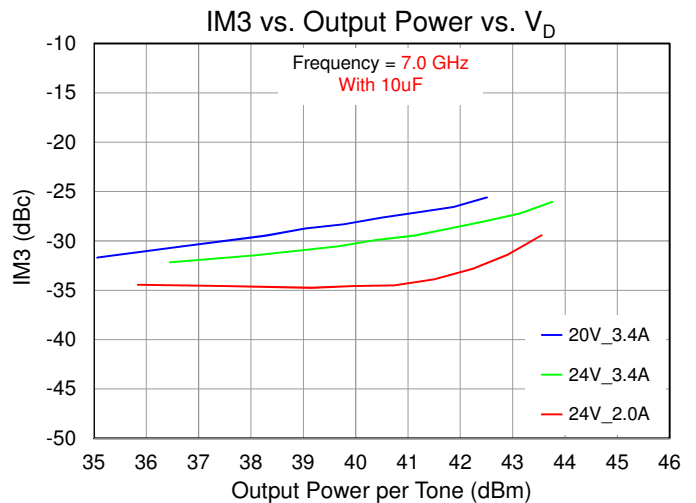
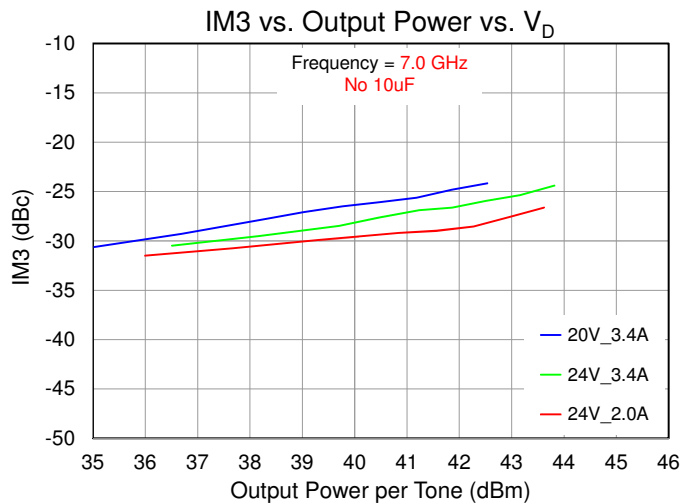
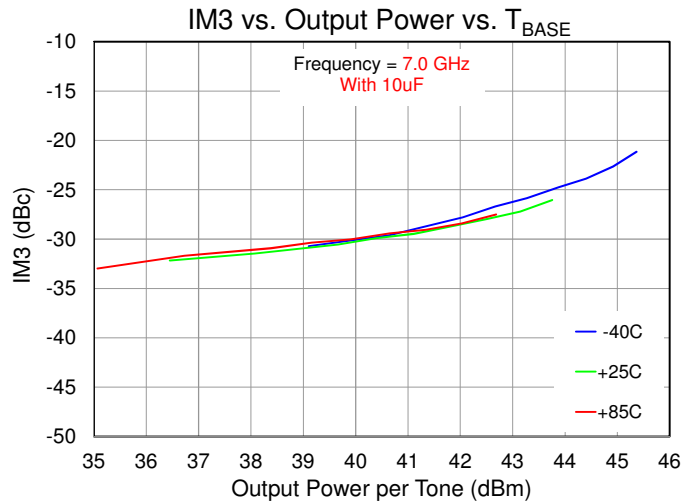
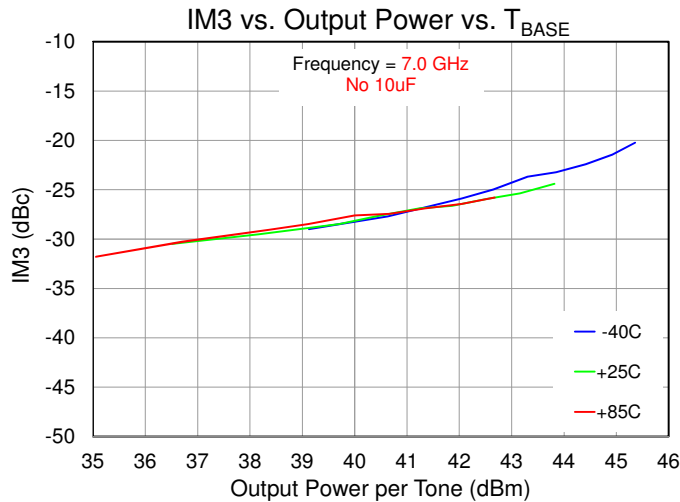
Performance Plots – Large Signal

Test conditions, unless otherwise noted: CW $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$, Tone Spacing = 5 MHz, $T_{BASE} = +25\text{ }^\circ\text{C}$, with/without 10uF at drain (C9, C12)



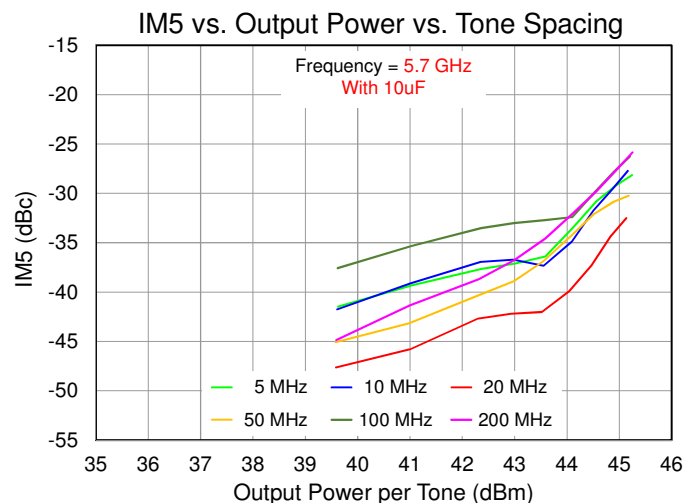
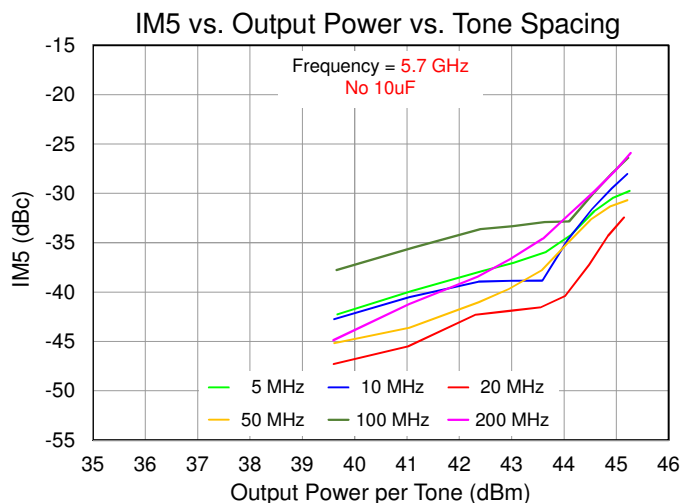
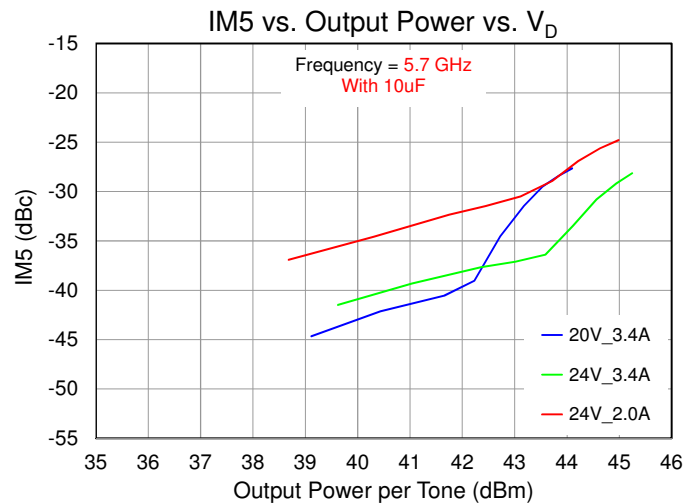
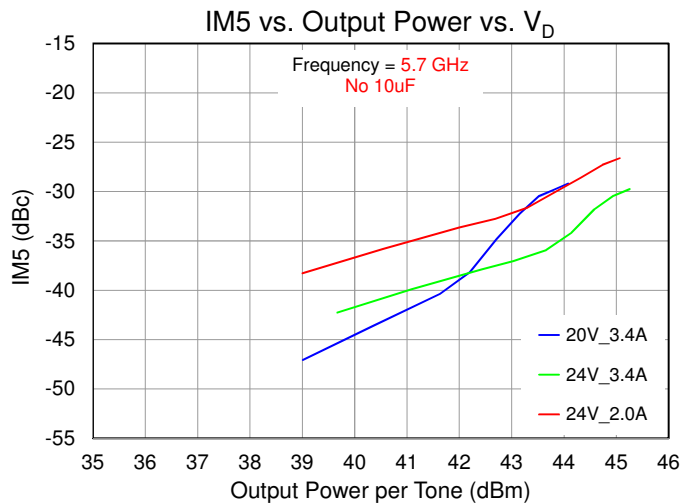
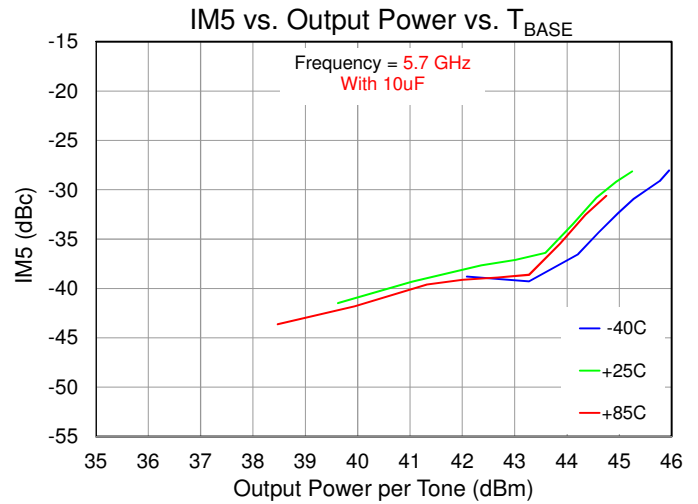
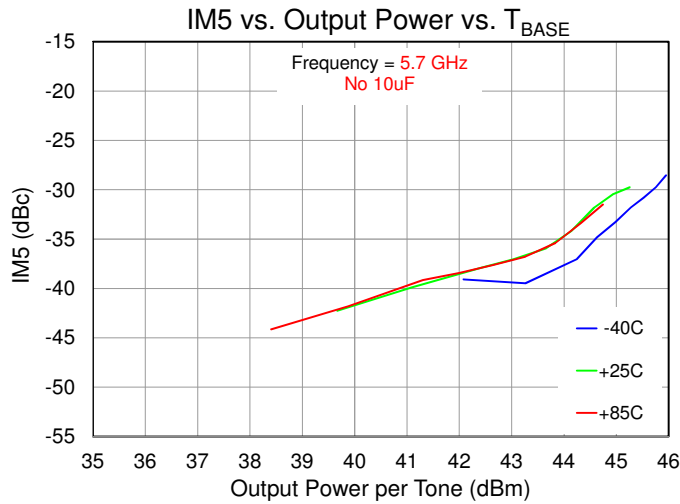
Performance Plots – Large Signal

Test conditions, unless otherwise noted: CW $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$, Tone Spacing = 5 MHz, $T_{BASE} = +25\text{ }^\circ\text{C}$, with/without 10uF at drain (C9, C12)



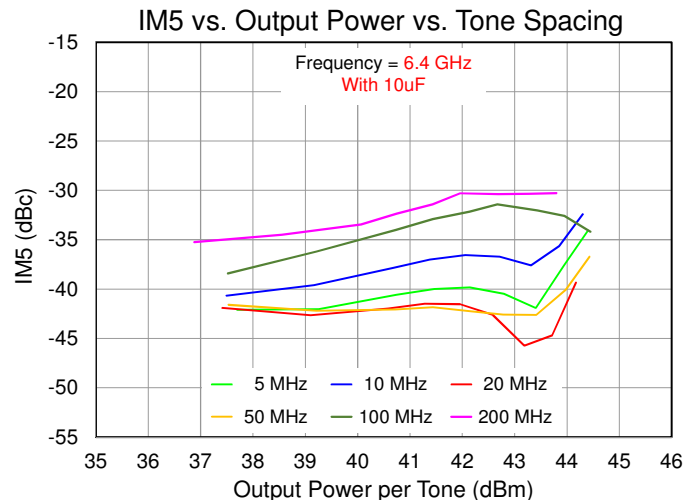
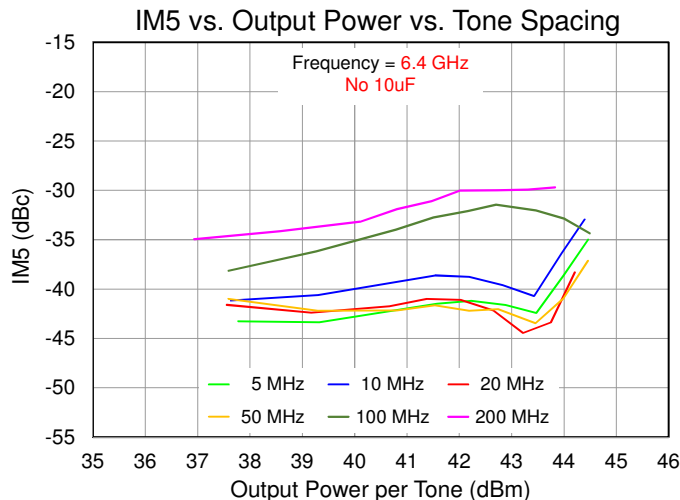
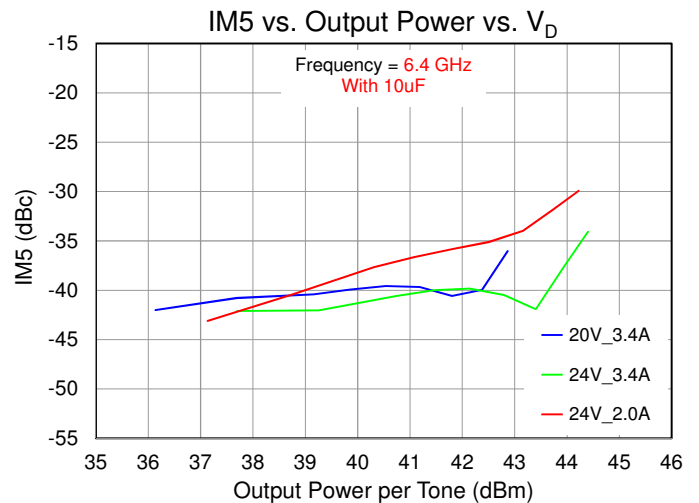
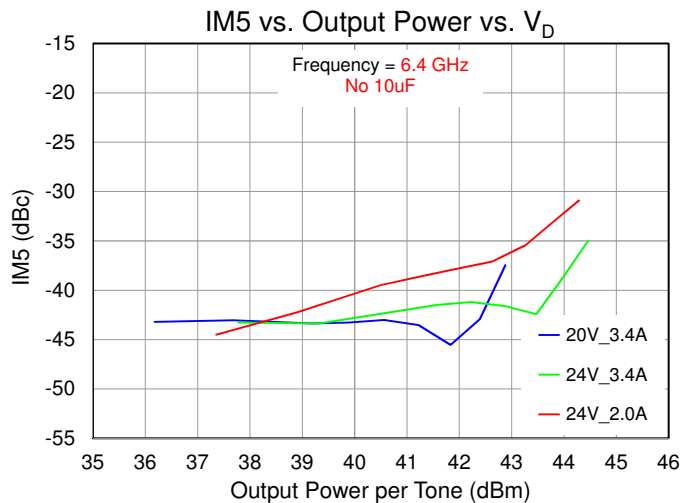
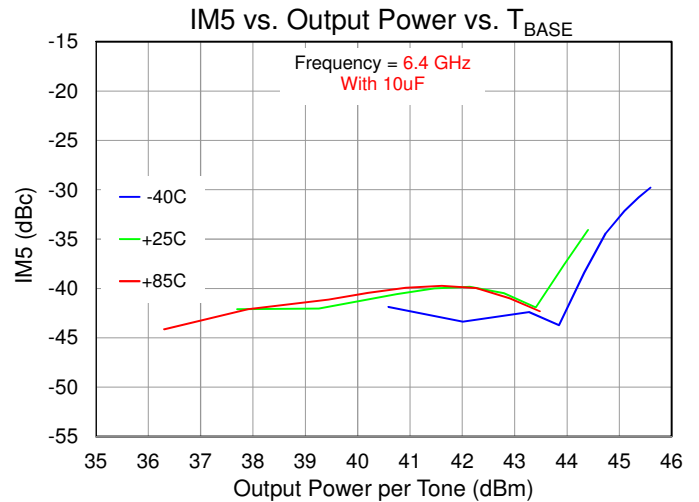
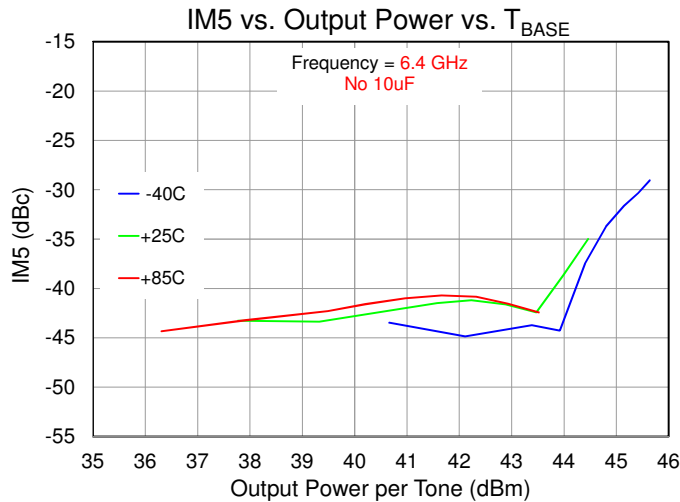
Performance Plots – Linearity

Test conditions, unless otherwise noted: CW $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$, Tone Spacing = 5 MHz, $T_{BASE} = +25\text{ }^\circ\text{C}$, with/without 10uF at drain (C9, C12)



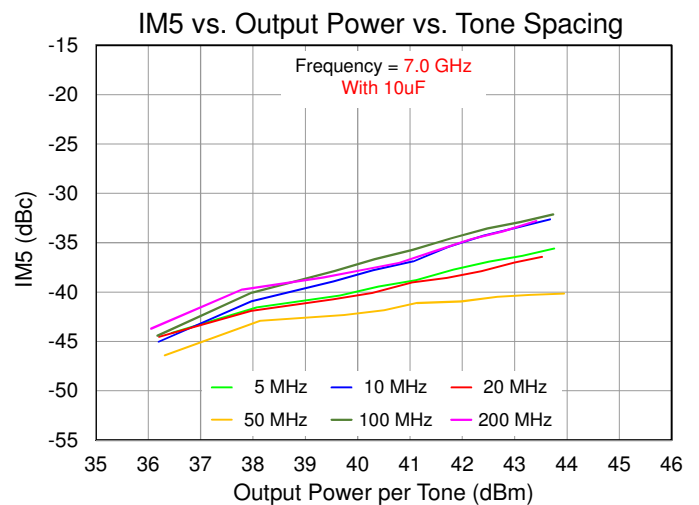
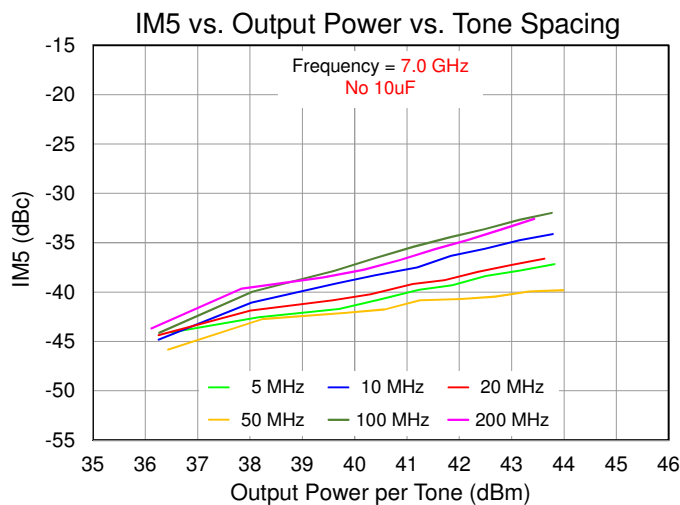
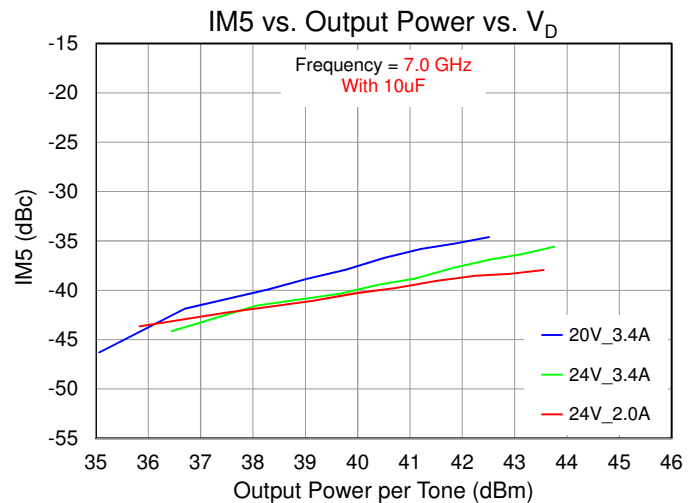
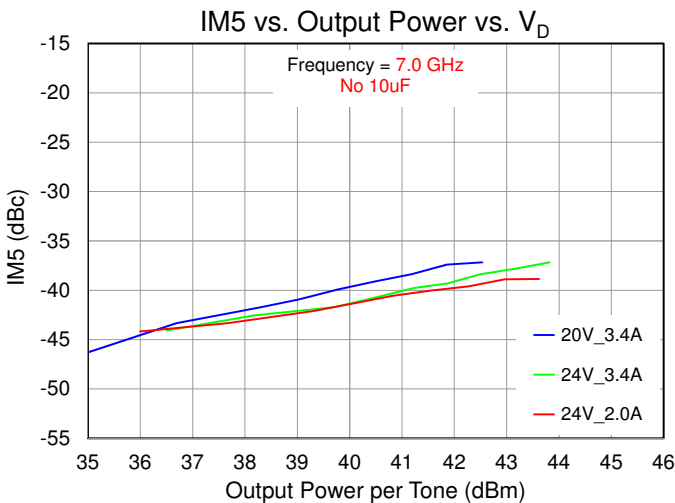
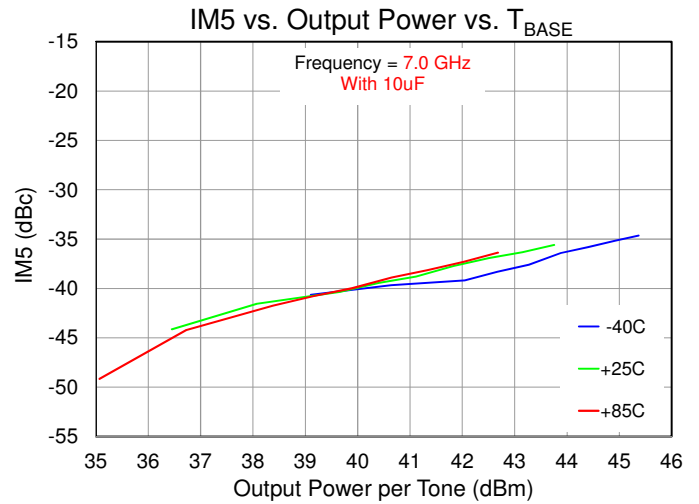
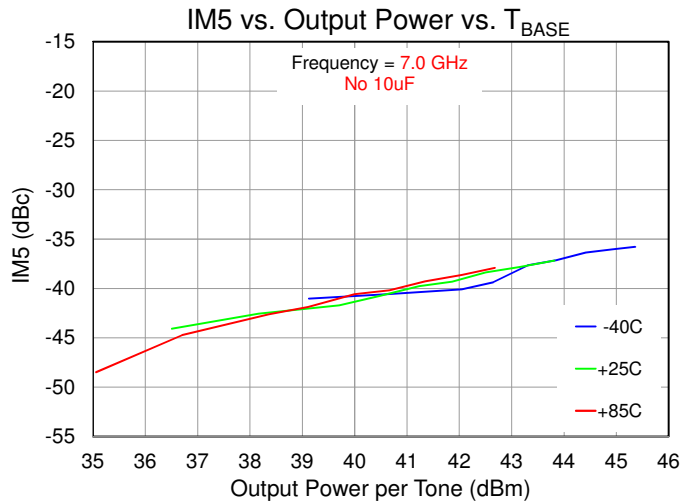
Performance Plots – Linearity

Test conditions, unless otherwise noted: CW $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$, Tone Spacing = 5 MHz, $T_{BASE} = +25\text{ }^\circ\text{C}$, with/without 10uF at drain (C9, C12)



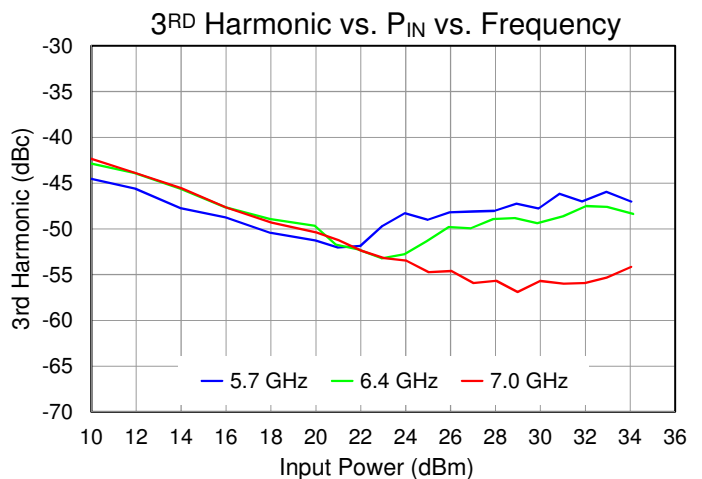
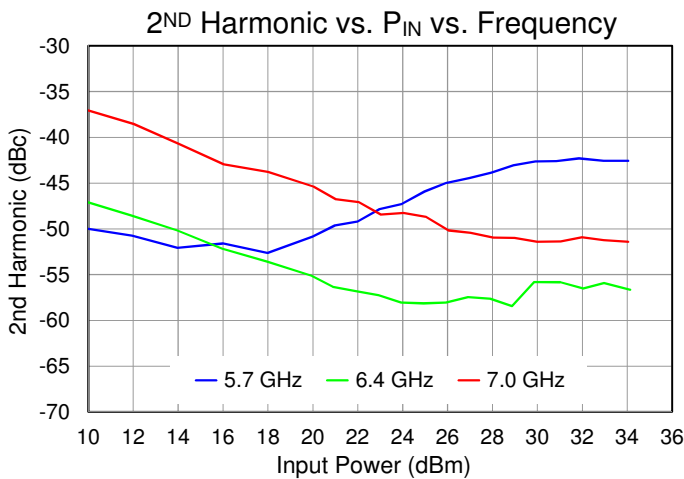
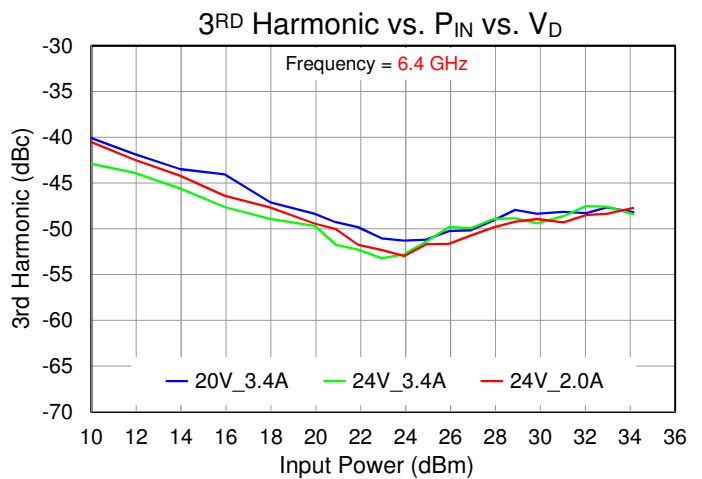
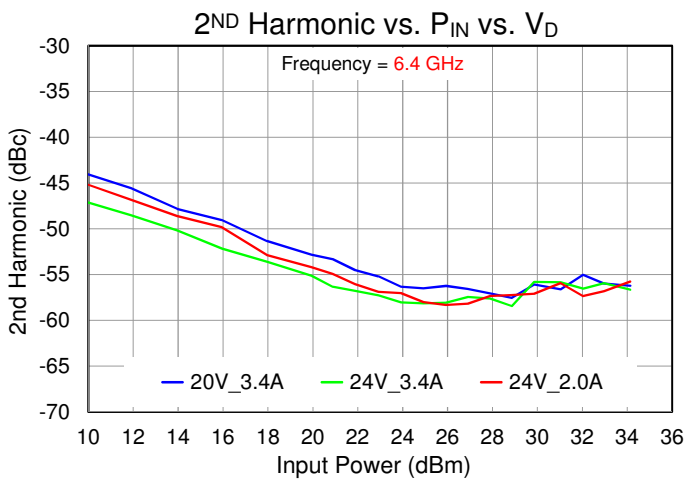
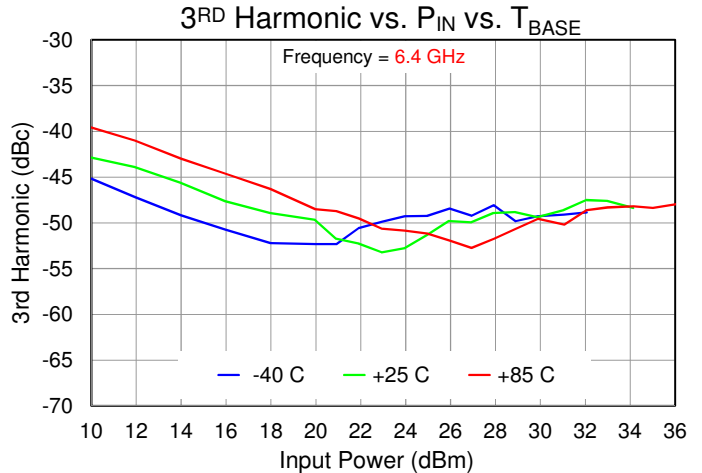
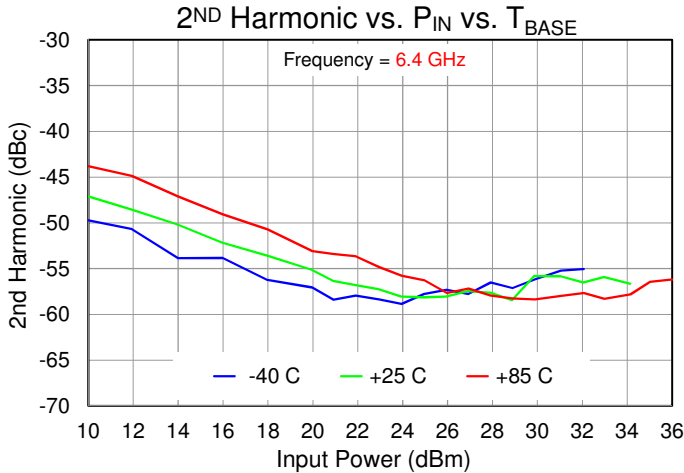
Performance Plots – Linearity

Test conditions, unless otherwise noted: **CW** $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$, Tone Spacing = 5 MHz, $T_{BASE} = +25\text{ }^\circ\text{C}$, with/without 10uF at drain (C9, C12)



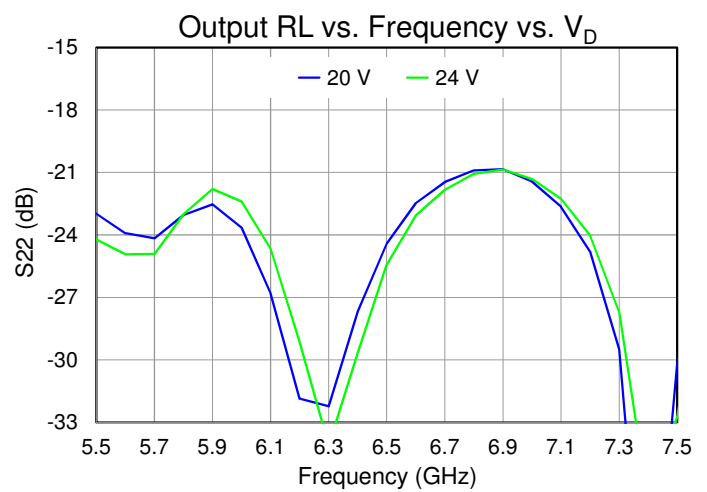
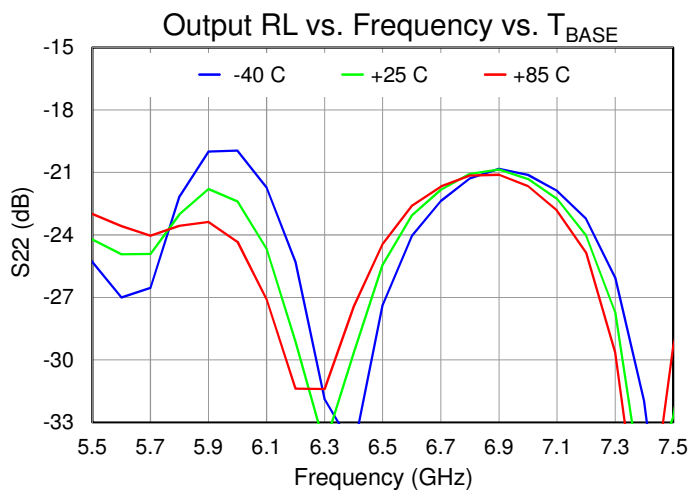
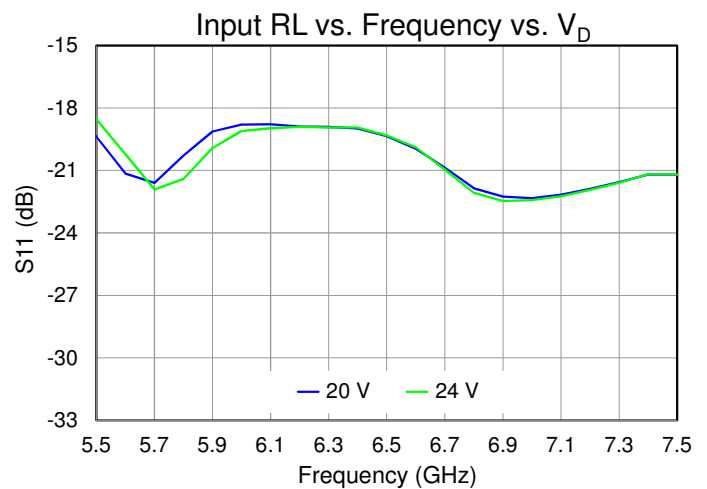
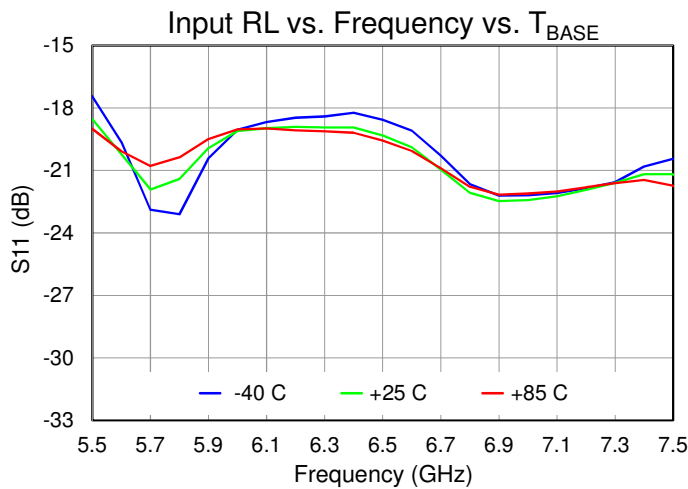
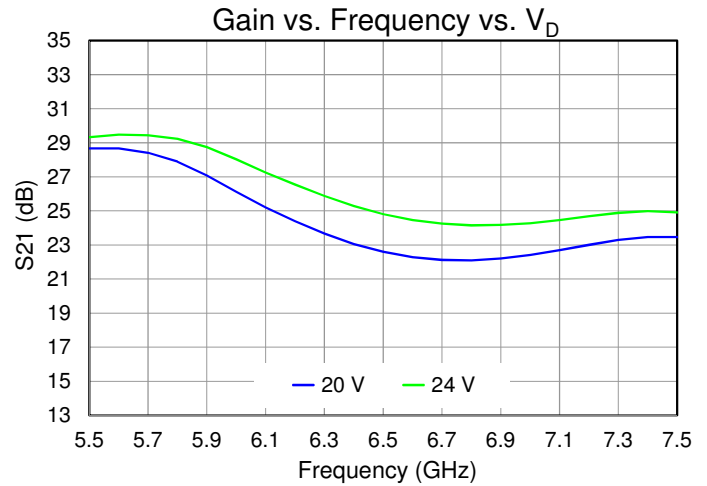
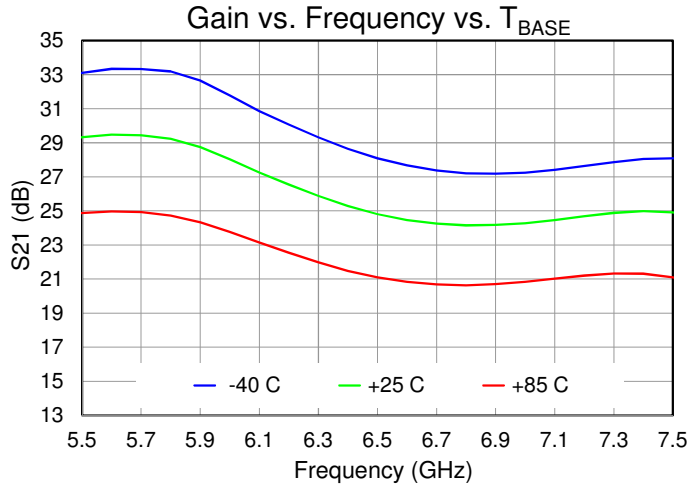
Performance Plots – Harmonics

Test conditions, unless otherwise noted: Pulsed $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$, Duty Cycle = 20%, $PW = 150\text{ }\mu\text{s}$, $T_{BASE} = +25\text{ }^\circ\text{C}$



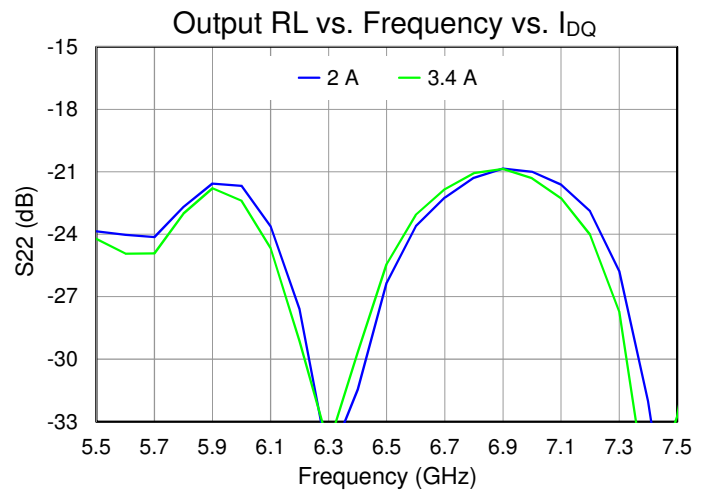
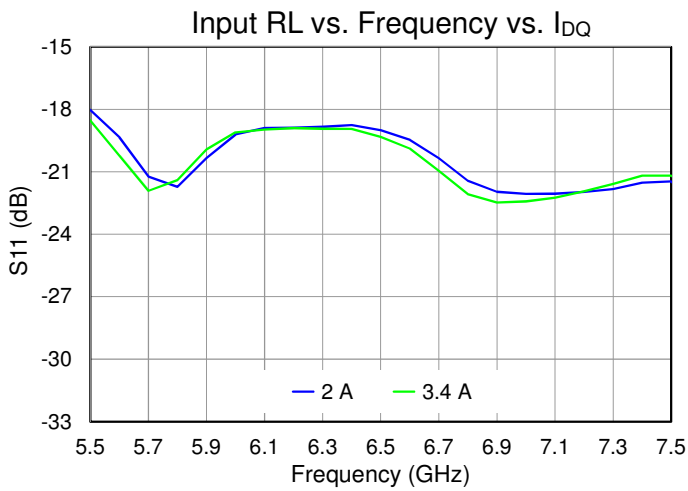
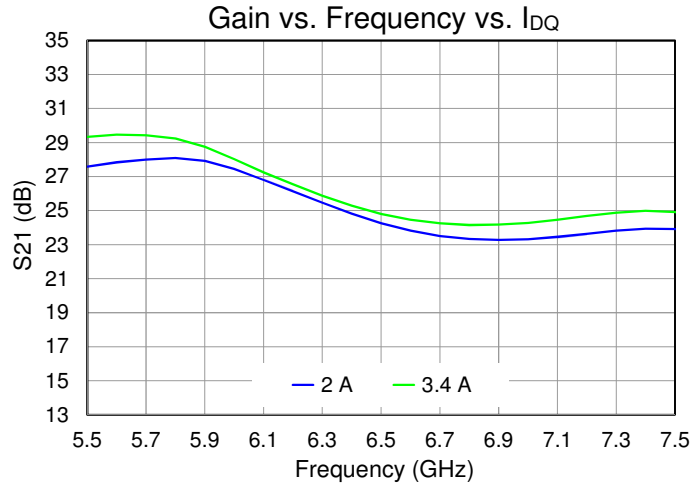
Performance Plots – Small Signal

Test conditions, unless otherwise noted: CW $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$, $T_{BASE} = +25\text{ }^\circ\text{C}$



Performance Plots – Small Signal

Test conditions, unless otherwise noted: CW $V_D = 24$ V, $I_{DQ} = 3.4$ A, $T_{BASE} = +25$ °C



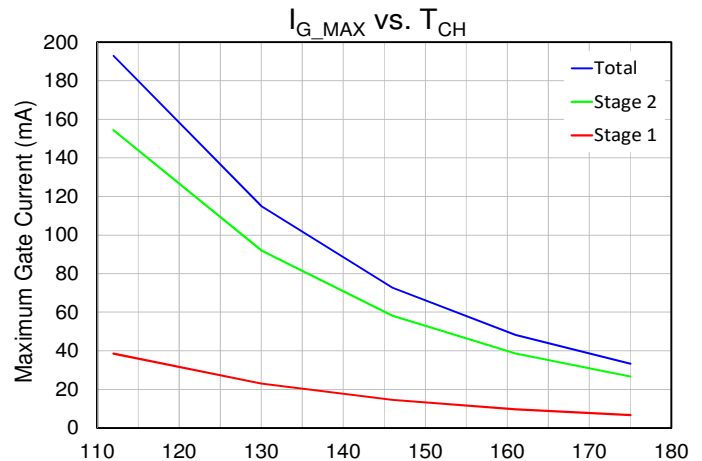
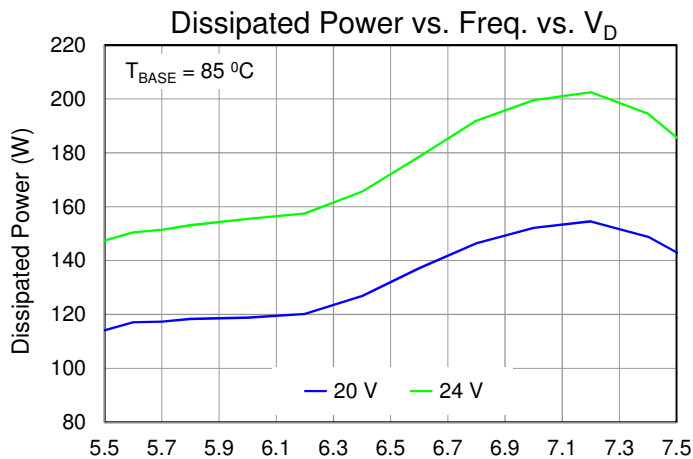
Thermal and Reliability Information

| Parameter | Test Conditions | Value | Units |
|--|---|-------|-----------------------------|
| Thermal Resistance, θ_{JC} ⁽¹⁾ | Quiescent | 0.40 | $^{\circ}\text{C}/\text{W}$ |
| Channel Temperature, T_{CH} ⁽²⁾ | $T_{\text{base}} = 85^{\circ}\text{C}$, $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$ $P_{\text{DISS}} = 81.6\text{ W}$ | 118 | $^{\circ}\text{C}$ |
| Thermal Resistance, θ_{JC} ⁽¹⁾ | Pulsed , $T_{\text{base}} = 85^{\circ}\text{C}$, $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$, Freq = 7 GHz, $I_{D_Drive} = 13\text{ A}$, DC = 20%, PW = 150 μs , $P_{\text{IN}} = 32\text{ dBm}$, $P_{\text{OUT,SAT}} = 50.3\text{ dBm}$ | 0.25 | $^{\circ}\text{C}/\text{W}$ |
| Channel Temperature, T_{CH} ⁽²⁾ | $P_{\text{DISS}} = 206\text{ W}$ | 137 | $^{\circ}\text{C}$ |
| Thermal Resistance, θ_{JC} ⁽¹⁾ | CW , $T_{\text{base}} = 85^{\circ}\text{C}$, $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$, Freq = 7 GHz, $I_{D_Drive} = 9\text{ A}$, $P_{\text{IN}} = 28\text{ dBm}$, $P_{\text{OUT}} = 46\text{ dBm}$ | 0.43 | $^{\circ}\text{C}/\text{W}$ |
| Channel Temperature, T_{CH} ⁽²⁾ | $P_{\text{DISS}} = 177\text{ W}$ | 161 | $^{\circ}\text{C}$ |

Notes:

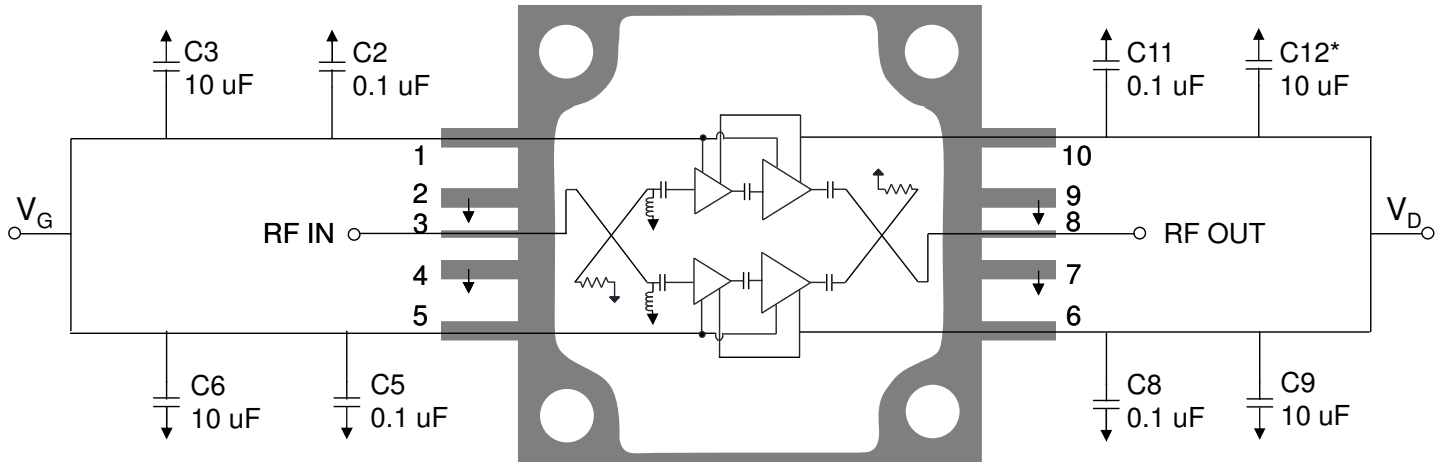
- Thermal resistance determined to the back of package (85°C)
- Channel temperature indicated is an IR scan equivalent temperature. Thermal resistance is calculated using this value. Additional information can be found in the Qorvo Applications Note “GaN Device TCHMAX Theta-JC and Reliability Estimates,” located here <https://www.qorvo.com/products/d/da006480>

Dissipated Power and Maximum Gate Current



Test conditions, unless otherwise noted: Pulsed, $V_D = 24\text{ V}$, $I_{DQ} = 3.4\text{ A}$, $P_{\text{IN}} = +32\text{ dBm}$, $T_{\text{BASE}} = +85^{\circ}\text{C}$

Applications Information



*C9, *C12: optional, to optimize linearity depending tone spacing, not populated on Qorvo's EVB, see performances on page 9 – 14

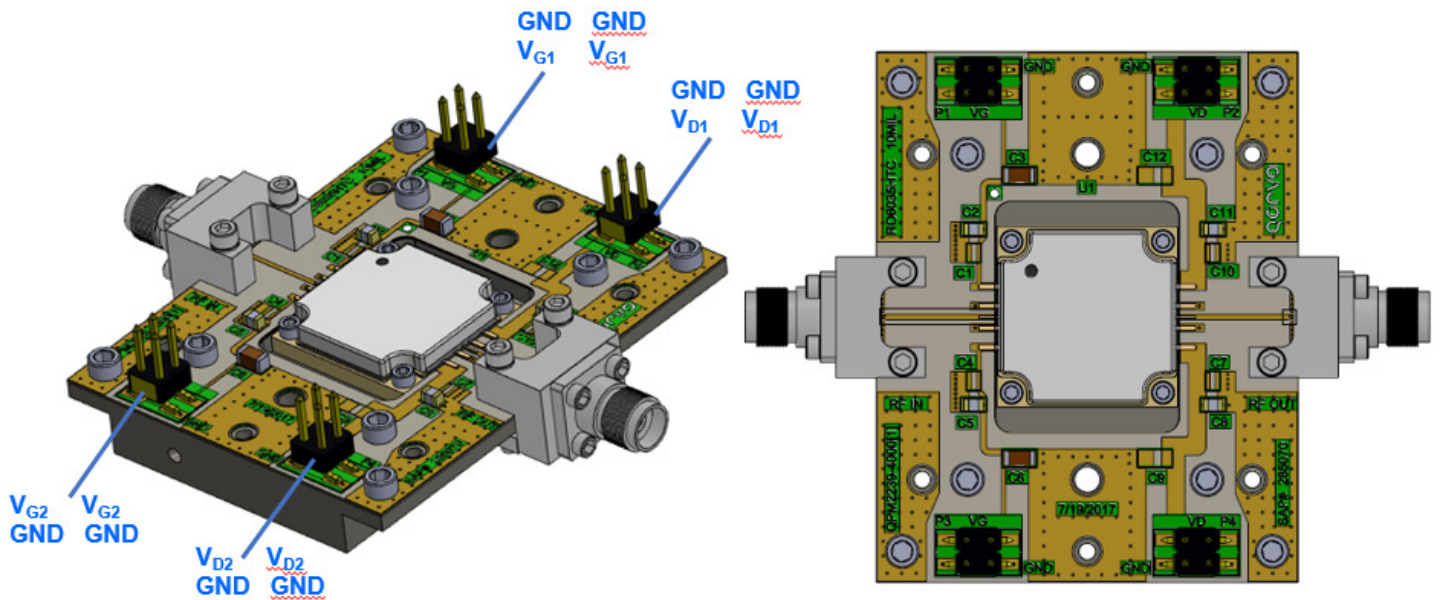
Bias-Up Procedure

1. Set I_D limit to 18 A, I_G limit to 180 mA
2. Set V_G to -5.0 V
3. Set V_D +24 V
4. Adjust V_G more positive until $I_{DQ} = 3.4$ A ($V_G \approx -2.5V \pm$ typical)
5. Apply RF signal

Bias-Down Procedure

1. Reduce V_G to -5.0 V. Ensure $I_{DQ} \sim 0$ mA
2. Set V_D to 0 V
4. Turn off RF signal
5. Turn off V_D supply
6. Turn off V_G supply

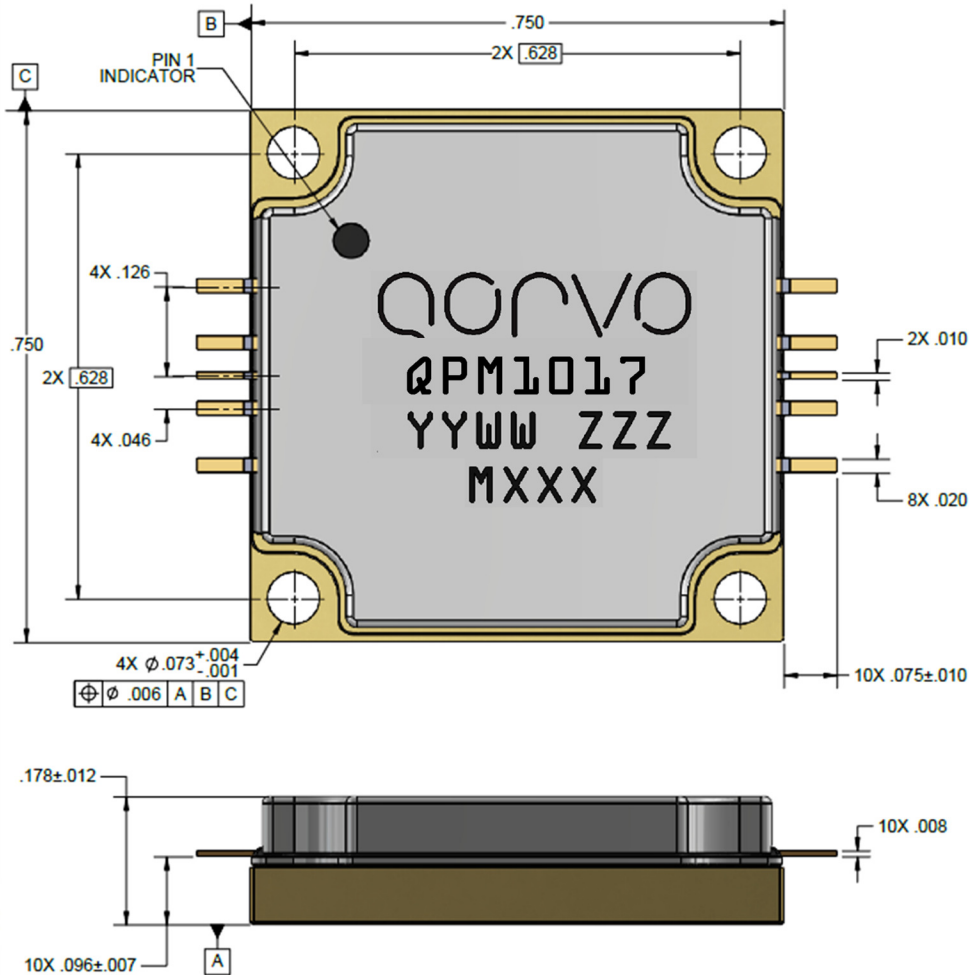
Evaluation Board (EVB) Layout Assembly



Bill of Materials

| Reference Des. | Value | Description | Manuf. | Part Number |
|------------------|--------|--|------------------------------------|-------------------------------|
| U1 | - | 100W C-Band GaN Power Amplifier Module | Qorvo | QPM1017 |
| C2, C5, C8, C11 | 0.1 uF | CAP, 0.1uF, ±10%, 50V, X7R, 0805 | Various | |
| C3, C6 | 10 uF | CAP, 10uF, 20%, 50V, 20%, X5R, 1206 | Various | |
| C9, C12 | 10 uF | CAP, 10uF, 20%, 50V, 20%, X5R, 1206 Optional, to optimize linearity depending tone spacing, see page 19 for recommendation, not populated on Qorvo EVB. | Various | |
| H1, H2, H3, H4 | - | CONN, HDR, 4 POS, 2 RAW, SMD, Au | Various | |
| J1, J2 | - | Connector, Female, End Launch, 1092-02A-5 | Southwest Microwave | 1092-02A-5 |
| S1 – S8 | - | Screw, Cap, Socket Head, 2-56X1/8" | Various | |
| S9 – S12 | - | Screw, Cap, Socket Head, 0-80X3/32" | Various | |
| PCB | - | PCB, Rogers 6035 10mils, 1oz Ni/Au plating 2 sides | Various | Custom |
| H-Block | - | H-Block, Copper C110, 1.744x 2.201 x 0.275T | Various | Custom |
| Solder | - | Paste, solder, Syntech, Sn62/Pb36/Ag2 | Inventec Performance Chemicals USA | Syntech, SN62, T3, 90.5, 250J |
| Epoxy | - | Epoxy, Ablebond 84-1LMI 3cc | Henkel Corporation | 84-1LMI |
| Thermal Compound | - | CHEM, Thermal Compound, Silver 5GR | Artic Silver | Artic Silver 5 AS5-3.5G |

Mechanical Information



NOTES:

1. MATERIALS
 PACKAGE BASE: COPPER
 LEADS: ALLOY 194
 LID: PLASTIC
 FINISH: GOLD
2. PART IS EPOXY SEALED
3. UNITS: INCHES
4. TOLERANCES (UNLESS NOTED):
 .XX = $\pm .01$
 .XXX = $\pm .005$
5. MARKINGS
 PART NUMBER: QPM1017
 WORK YEAR: YY
 WORK WEEK: WW
 SERIAL NUMBER: ZZZ
 BATCH ID: MXXX

Pin Description

| Pin No. | Symbol | Description |
|------------|-------------------|---|
| 1 | V _{G1} | Gate voltage Amp 1. External bypassing required; refer to page 19 for recommendation |
| 2, 4, 7, 9 | Ground | Must be grounded to PCB |
| 3 | RF _{IN} | RF Input. Matched to 50 Ω, DC blocked, DC shorted to ground |
| 5 | V _{G2} | Gate voltage Amp 2. External bypassing required; refer to page 19 for recommendation |
| 6 | V _{D2} | Drain voltage Amp 2. External bypassing required; refer to page 19 for recommendation |
| 8 | RF _{OUT} | RF Output. Matched to 50 Ω, DC blocked |
| 10 | V _{D1} | Drain voltage Amp 1. External bypassing required; refer to page 19 for recommendation |

Assembly Notes

- Carefully clean the PC board, base plate, and package leads with alcohol. Allow it to dry fully.
- To improve the thermal and RF performance, Qorvo recommends attaching a heat sink to the bottom of the package and apply either a thermal compound (Arctic Silver 5 recommended) or a .004 inch (maximum thickness) Indium shim between the heat sink and the package. Refer to the applications note [Application of Arctic Silver 5 Thermal Compound and Indium Shims for Qorvo CP-style Packaged Components](#) for more information.
- The component leads should be manually soldered. Apply a low residue solder alloy meeting J-STD-001 (ROL0, ROL1 or equivalent) with a liquidus temperature below 220 °C to each pin of the TGA/QPA/QPMxxxx. The use of low residue/no-clean flux (ROL0, ROL1) is recommended. The package lead temperature should not exceed 260 deg C. Each solder connection should be completed within 2 to 5 seconds. Adding flux during hand soldering of the component leads with localized spot cleaning is acceptable. Soldering irons meeting the requirements of J-STD-001, Appendix A are acceptable.
- The leads should be soldered in a staggered or star pattern from side to side, and never solder two adjacent leads. This allows the heat to dissipate on each lead, and not cause the adjacent leads to become de-soldered and damaged or displaced.



- The packaged part should not be subjected to conventional SMT automated solder reflow processes.
- (The following is for information only. There are many variables in a second level assembly that Qorvo does not control, so Qorvo does not recommend an absolute torque value.) Use screws to attach the component to the heat sink. A suggested final torque value is 16 in-oz. for a 0-80 screw. Start with screws finger tight, then torque to 8 in-oz., then torque to final value. Use the following tightening pattern:



Handling Precautions

| Parameter | Rating | Standard |
|----------------------------------|--------|-------------------------|
| ESD – Human Body Model (HBM) | 1A | ANSI/ESD/JEDEC JS-001 |
| ESD – Charged Device Model (CDM) | C2a | ANSI/ESD/JEDEC JS-002 |
| MSL – Moisture Sensitivity Level | N/A | Blank, null, no content |



Caution!

ESD-Sensitive Device

RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Product uses RoHS Exemption 7c-I to meet RoHS Compliance requirements
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- PFOS Free
- SVHC Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: www.qorvo.com

Tel: 1-844-890-8163

Email: customer.support@qorvo.com

Important Notice

The information contained herein is believed to be reliable; however, Qorvo makes no warranties regarding the information contained herein and assumes no responsibility or liability whatsoever for the use of the information contained herein. All information contained herein is subject to change without notice. Customers should obtain and verify the latest relevant information before placing orders for Qorvo products. The information contained herein or any use of such information does not grant, explicitly or implicitly, to any party any patent rights, licenses, or any other intellectual property rights, whether with regard to such information itself or anything described by such information. **THIS INFORMATION DOES NOT CONSTITUTE A WARRANTY WITH RESPECT TO THE PRODUCTS DESCRIBED HEREIN, AND QORVO HEREBY DISCLAIMS ANY AND ALL WARRANTIES WITH RESPECT TO SUCH PRODUCTS WHETHER EXPRESS OR IMPLIED BY LAW, COURSE OF DEALING, COURSE OF PERFORMANCE, USAGE OF TRADE OR OTHERWISE, INCLUDING THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE.**

Without limiting the generality of the foregoing, Qorvo products are not warranted or authorized for use as critical components in medical, life-saving, or life-sustaining applications, or other applications where a failure would reasonably be expected to cause severe personal injury or death.

Copyright 2024 © Qorvo, Inc. | Qorvo is a registered trademark of Qorvo, Inc.

Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

 [View QPM1017 on WIN SOURCE](#)

 [Qorvo US Inc. Information](#)

Optimize Your Supply Chain with WIN SOURCE Solutions

-  Global Sourcing Solution
-  Obsolete Management
-  Cost Control Management
-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management